LTM4636-1

40A µModule Regulator with Overvoltage/ Overtemperature Protection **DESCRIPTION**

The LTM[®]4636-1 is a 40A step-down µModule[®] (power

module) switching regulator with stacked inductor as a

heat sink for heat dissipation and cooler operation in a

small package. The LTM4636-1 detects overtemperature

and input/output overvoltage conditions and can trip an up-

stream power supply or circuit breaker to protect itself and

its load. The exposed inductor as a heat sink permits direct

contact with airflow from any direction. The LTM4636-1

can deliver 40W (12VIN, 1VOUT, 40A, 200LFM) with only

40°C rise over the ambient temperature. Full-power 40W

is delivered up to 83°C ambient and half-power 20W is

The LTM4636-1 operates at 92%, 90% and 88% efficiency

delivering 15A, 30A and 40A, respectively, to a 1V load

 $(12V_{IN})$. The µModule regulator is scalable where four

in current sharing deliver 160W with only 40°C rise and 88% efficiency ($12V_{IN}$, $1V_{OUT}$, 400LFM). The LTM4636-1

is offered in 16mm × 16mm × 7.07mm BGA package. All registered trademarks and trademarks are the property of their respective owners. Protected

by U.S. Patents, including 5481178, 5847554, 6580258, 6304066, 6476589, 6774611,

supported at 110°C ambient.

6677210, 8163643.

FEATURES

ANALOG

- Overtemperature, Input/Output Overvoltage Protection
- Trips Upstream Power Source or Circuit Breaker

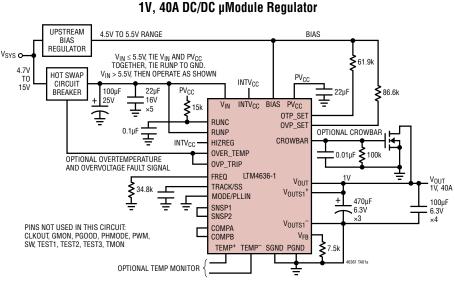
OWER BY

- Stacked Inductor Acts as Heat Sink
- Wide Input Voltage Range: 4.7V to 15V
- 0.6V to 3.3V Output Voltage Range
- ±1.3% Total DC Output Voltage Error (-40°C to 125°C)
- Differential Remote Sense Amplifier for Precision Regulation
- Current Mode Control/Fast Transient Response
- Frequency Synchronization
- Parallel Current Sharing (Up to 240A)
- 88% Efficiency (12V_{IN}, 1V_{OUT}) at 40A
- Overcurrent Foldback Protection
- Overtemperature Shutdown
- 16mm × 16mm × 7.07mm BGA Package

APPLICATIONS

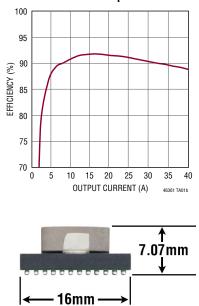
- Telecom Servers and Networking Equipment
- Industrial Equipment and Medical Systems

TYPICAL APPLICATION



See the LTM4636 for simpler circuit and fewer features.

$12V_{IN}$, $1V_{OUT}$ Efficiency at 350kHz vs Output Current



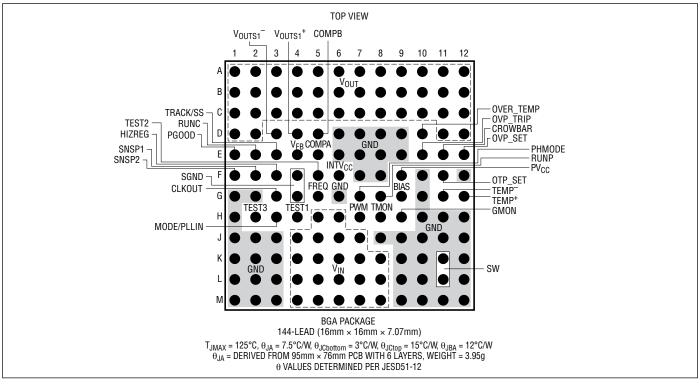
ABSOLUTE MAXIMUM RATINGS (Note 1)

| V _{IN} , SW, HZBREG, RUNP, OVR_TRIP, | |
|--|---|
| OVER TEMP0.3V to 16V | (|
| V _{OUT} –0.3V to 3.5V | / |
| PGOOD, RUNC, TMON, PV _{CC} , MODE/PLLIN, | |
| PHMODE, FREQ, TRACK/SS, TEST1, TEST2, | |
| V _{OUTS1} ⁻ , V _{OUTS1} +, SNSP1, SNSP2, TEST3, | |
| OVP_SET, CROWBAR0.3V to INTV _{CC} (5V) | |
| VFB, COMPA, COMPB (Note 6)0.3V to 2.7V | (|
| BIAS–0.3V to 6V | 1 |
| | |

| PV _{CC} Additional Output Current TEMP ⁺ , TEMP ⁻ | |
|---|------------------|
| INTV _{CC} Peak Output Current (Note 6) | |
| Internal Operating Temperature Range | |
| (Note 2) | .–40°C to 125°C |
| Storage Temperature Range | . –55°C to 125°C |
| Reflow (Peak Body) Temperature | 250°C |

Note: PWM, CLKOUT, and GMON are outputs only.

PIN CONFIGURATION





ORDER INFORMATION http://www.linear.com/product/LTM4636-1#orderinfo

| LEAD FREE FINISH | TRAY | PART MARKING* | PACKAGE DESCRIPTION | TEMPERATURE RANGE |
|------------------|-----------------|---------------|-------------------------------------|-------------------|
| LTM4636-1EY#PBF | LTM4636-1EY#PBF | LTM4636-1 | 144-Lead (16mm × 16mm × 7.07mm) BGA | -40°C to 125°C |
| LTM4636-1IY#PBF | LTM4636-1IY#PBF | LTM4636-1 | 144-Lead (16mm × 16mm × 7.07mm) BGA | -40°C to 125°C |

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

This product is only offered in trays. For more information go to: http://www.linear.com/packaging/

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the specified internal operating temperature range (Note 2), otherwise specifications are at T_A = 25°C. V_{IN} = 12V, per the Typical Application in Figure 20.

| SYMBOL | PARAMETER | CONDITIONS | | MIN | ТҮР | MAX | UNITS |
|---|--|--|---|-------------|-----------------------|-------------------|----------------------|
| V _{IN} | Input DC Voltage | $V_{IN} \le 5.5V$, Tie V _{IN} and PV _{CC} Together, Tie RUNP to GND | | 4.70 | | 15 | ١ |
| V _{OUT} | V _{OUT} Range | | | 0.6 | | 3.3 | ١ |
| V _{OUT(DC)} | DC Output Voltage, Total Variation with Line and Load | $\begin{array}{l} C_{IN} = 22\mu F \times 5 \\ C_{OUT} = 100\mu F \times 4 \ Ceramic, \ 470\mu F \ POSCAP \times 3 \\ R_{FB} = 40.2k, \ MODE_PLLIN = GND \\ V_{IN} = 4.70V \ to \ 15V, \ I_{OUT} = 0A \ to \ 40A \ (Note \ 4) \end{array}$ | • | 1.4805 | 1.50 | 1.5195 | V |
| Input Specificat | ions | | - | | | | |
| V _{RUNC} | RUNC Pin On Threshold | V _{RUNC} Rising | | 1.1 | 1.22 | 1.35 | V |
| V _{RUNCHYS} | RUNC Pin On Hysteresis | | | | 150 | | m۷ |
| V _{RUNP} | RUNP Pin On Threshold | RUNP Pin Rising | | 0.7 | 0.8 | 0.9 | V |
| RUNP HYS | RUNP Pin Hysteresis | | | | 60 | | m۷ |
| HIZREG | HIZREG Input Threshold | V _{IN} = 12V, RUNC = 5V, RUNP = V _{IN} , V _{OUT} = 1.5V | | | 2.3 | | V |
| HIZREG HYS | HIZREG Hysteresis | $V_{IN} = 12V$, RUNC = 5V, RUNP = V_{IN} , $V_{OUT} = 1.5V$ | | | 0.8 | | V |
| I _{Q(VIN)} | Input Supply Bias Current | $ \begin{array}{l} V_{IN} = 12V, \ V_{OUT} = 1.5V, \ Burst \ Mode \ Operation, \ I_{OUT} = 0.1A \\ V_{IN} = 12V, \ V_{OUT} = 1.5V, \ Pulse-Skipping \ Mode, \ I_{OUT} = 0.1A \\ V_{IN} = 12V, \ V_{OUT} = 1.5V, \ Switching \ Continuous, \ I_{OUT} = 0.1A \\ Shutdown, \ RUN = 0, \ V_{IN} = 12V \\ \end{array} $ | | | 16 23 105 30 | | mA mA mA μA |
| I _{S(VIN)} | Input Supply Current | $V_{IN} = 5V, V_{OUT} = 1.5V, I_{OUT} = 40A$ $V_{IN} = 12V, V_{OUT} = 1.5V, I_{OUT} = 40A$ | | | 14.7 5.66 | | A |
| Output Specifica | ations | | | | | | |
| I _{OUT(DC)} | Output Continuous Current Range | V _{IN} = 12V, V _{OUT} = 1.5V (Note 4) | | 0 | | 40 | A |
| $\frac{\Delta V_{OUT} \text{ (Line)}}{V_{OUT}}$ | Line Regulation Accuracy | V_{OUT} = 1.5V, V_{IN} from 4.70V to 15V I_{OUT} = 0A | • | • 0.02 0.06 | | 0.06 | %/V |
| $\frac{\Delta V_{OUT} \text{ (Load)}}{V_{OUT}}$ | Load Regulation Accuracy | $V_{OUT} = 1.5V, I_{OUT} = 0A \text{ to } 40A, V_{IN} = 12V \text{ (Note 4)}$ | • | • 0.2 0.35 | | 0.35 | % |
| V _{OUT(AC)} | Output Ripple Voltage | $I_{OUT} = 0A, C_{OUT} = 100\mu F \times 3$ Ceramic, 470 μ F × 3 POSCAP, $V_{IN} = 12V, V_{OUT} = 1.5V$ | | 15 | | mV _{P-P} | |
| $\Delta V_{OUT(START)}$ | Turn-On Overshoot | C _{OUT} = 100µF × 4 Ceramic, 470µF × 3 POSCAP, V _{OUT} = 1.5V, I _{OUT} = 0A, V _{IN} = 12V, TRACK/SS = 0.1µF | | | 5 | | mV |
| t _{START} | Turn-On Time | C _{OUT} = 100µF × 3 Ceramic, 470µF × 3 POSCAP, No Load, TRACK/SS = 0.001µF, V _{IN} = 12V | | | 750 | | μs |
| ΔV _{OUTLS} | Peak Deviation for Dynamic Load | Load: 0% to 50% to 0% of Full Load C _{OUT} = 100µF × 4 Ceramic, 470µF × 3 POSCAP, V _{IN} = 12V, V _{OUT} = 1.5V, CFF = 22pF | | | 45 | | mV |
| t _{SEΠLE} | Settling Time for Dynamic Load Step | Load: 0% to 50% to 0% of Full Load, $V_{IN} = 5V$, $C_{OUT} = 100\mu F \times 4$ Ceramic, $470\mu F \times 3$ POSCAP, $V_{IN} = 12V$, $V_{OUT} = 1.5V$, CFF = 22pF | | 25 | | μs | |
| I _{OUTPK} | Output Current Limit | V _{IN} = 12V, V _{OUT} = 1.5V V _{IN} = 5V, V _{OUT} = 1.5V | | | 54 54 | | A A |
| Control Section | | | | | | | |
| V _{FB} | Voltage at V _{FB} Pin | $I_{OUT} = 0A, V_{OUT} = 1.5V$ | | 0.594 | 0.600 | 0.606 | V |
| I _{FB} | Current at V _{FB} Pin | (Note 6) | | | -30 | -100 | nA |
| V _{OVL} | Feedback Overvoltage Lockout | Measure at V _{OUTS1} | • | 5 7.5 10 | | % | |
| I _{TRACK/SS} | Track Pin Soft-Start Pull-Up Current | TRACK/SS = 0V, Default 750µs Turn on with TRACK/SS Tied to INTV _{CC} | | 1.1 | 1.35 | 1.6 | μA |
| t _{ON(MIN)} | Minimum On-Time | (Note 3) | | | 100 | | ns |
| R _{FBHI} | Resistor Between V_{OUTS1} and V_{FB} Pins | | | | 4.99 | | kΩ |

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the specified internal operating temperature range (Note 2), otherwise specifications are at T_A = 25°C. V_{IN} = 12V, per the typical application in Figure 20.

| SYMBOL | PARAMETER | CONDITIONS | | MIN | TYP | MAX | UNITS |
|-------------------------------|---|---|---------------|-----|-------------|-----|----------|
| Remote Sense Am | plifier | | | | | | |
| A _{V(VFB)} | V _{FB} Differential Gain | (Note 6) | | | 1 | | V/V |
| GBP V _{FB} Path | Gain Bandwidth Product | (Note 5) | | | 4 | | MHz |
| General Control o | r Monitor Pins | | • | | | | |
| OVP \(\Delta t) | OVP to OVP_TRIP | OVP Response Time | | | 500 | | ns |
| Crowbar ∆t | OVP to CROWBAR | OVP Response Time to CROWBAR | | | 500 | | ns |
| OVP Delay | OVP to OVER_TEMP | OVP_TEMP to OVP_TEMP Response Time | | | 8 | | μs |
| OVP_Trip Sink | OVP_TRIP Sink Current | $V_{CE} \le 0.4V$ | | | | 15 | mA |
| OTP_Trip Sink | OVER_TEMP Sink Current | $V_{CE} \le 0.4V$ | | | | 15 | mA |
| Crowbar Source | CROWBAR Source Current | $V_{CROWBAR} \ge 3.0V$ | | | 15 | | mA |
| OTP_SET | Overtemperature Set Register | | | | 24.9 | | kΩ |
| OVP_SET | Overvoltage Set Register | | | | 24.9 | | kΩ |
| I _{TMON} | | Temperature Monitor Current, $T_J = 25^{\circ}C$ Into 24.9k Ω Temperature Monitor Current, $T_J = 150^{\circ}C$ Into 24.9k Ω | | 38 | 40.3 58 | 44 | μA μA |
| I _{TMON(SLOPE)} | | Temperature Monitor Current Slope, $R_{TMON} = 24.9 k\Omega$ | | | 0.144 | | µA/°C |
| V _{PGOOD} | PGOOD Trip Level | V _{FB} With Respect to Set Output V _{FB} Ramping Negative V _{FB} Ramping Positive | | | -7.5 7.5 | | % |
| V _{PGL} | PGOOD Voltage Low | $I_{PGOOD} = 2mA$ | | | 0.2 | 0.4 | V |
| t _{PGOOD} | V _{PGOOD} High-to-Low Delay | | | | 65 | | μs |
| IPGOOD(OFF) | PGOOD Leakage Current | V _{PG00D} = 5V | | -2 | | 2 | μA |
| V _{PG1(HYST)} | PGOOD Trip Level Hysteresis | | | | 2.5 | | % |
| INTV _{CC} Linear Reg | gulator | | | | | | |
| VINTVCC | Internal V _{CC} Voltage Source | 6V < V _{IN} < 15V | | 5.3 | 5.5 | 5.7 | V |
| V _{INTVCC} Load Reg | INTV _{CC} Load Regulation | I _{CC} = 0mA to 10mA | | | 0.5 | | % |
| UVLO HYS | Controller UVLO Hysteresis | (Note 6) | | | 0.5 | | V |
| PV _{CC(UVL0)} | Drivers and Power MOSFETs UVLO | PV _{CC} Rising | ising 3.5 3.8 | | 4.1 | V | |
| PV _{CC(HYS)} | PV _{CC} UVLO Hysteresis | | | | 0.45 | | V |
| PV _{CC} | Power Stage Bias | 12V Input, PV _{CC} Load = 50mA | | | 5.0 | | V |
| BIAS | External Bias for OTP and OVP Function | Range Operating | | 4 | 5.0 | 5.5 | V |

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the specified internal operating temperature range (Note 2), otherwise specifications are at T_A = 25°C. V_{IN} = 12V, per the typical application in Figure 20.

| SYMBOL | PARAMETER | CONDITIONS | | MIN | ТҮР | MAX | UNITS |
|-------------------------|---|---|--|---------------------------------|------------------------------|-----------------------------------|--|
| Oscillator and F | hase-Locked Loop | | | 1 | | | 1 |
| f _{OSC} | Oscillator Frequency V _{PHSMD} = 0V | $\begin{array}{l} R_{FREQ} = 30.1 \mathrm{k}\Omega \\ R_{FREQ} = 47.5 \mathrm{k}\Omega \\ R_{FREQ} = 54.9 \mathrm{k}\Omega \\ R_{FREQ} = 75.0 \mathrm{k}\Omega \\ Maximum Frequency \\ Minimum Frequency \end{array}$ | • | 210 540 625 945 1.2 | 250 600 750 1.05 | 290 660 825 1.155 0.2 | kHz kHz kHz MHz MHz MHz |
| I _{FREQ} | FREQ Pin Output Current | $V_{FREQ} = 0.8V$ | | 19 | 20 | 21 | μA |
| R _{MODE/PLLIN} | MODE_PLLIN Input Resistance | | | | 250 | | kΩ |
| V _{MODE/PLLIN} | PLLIN Input Threshold | V _{MODE/PLLIN} Rising V _{MODE/PLLIN} Falling | | | 2 1.2 | | V V |
| V _{CLKOUT} | Low Output Voltage High Output Voltage | Verified Levels Measurements on CLKOUT | | | 0.2 5.2 | | V V |
| PWM-CLKOUT | PWM to Clockout Phase Delay | $V_{PHMODE} = 0V$ $V_{PHMODE} = 1/4 INTV_{CC}$ $V_{PHMODE} = Float$ $V_{PHMODE} = 3/4 INTV_{CC}$ $V_{PHMODE} = INTV_{CC}$ | | | 90 90 120 60 180 | | Deg Deg Deg Deg Deg |
| PWM/PWMEN Ou | tputs | | L. L | | | | |
| PWM | PWM Output High Voltage | I _{LOAD} = 500μA | | 5.0 | | | V |
| | PWM Output Low Voltage | $I_{LOAD} = -500\mu A$ | | | | 0.5 | V |
| Temperature Di | ode | · | L. L | | | | |
| Diode V- | Diode Forward Voltage | L = 100µA TEMP+ to TEMP- | | 1 | 0 508 | | V |

| Diode V _F | Diode Forward Voltage | $I = 100\mu A$, TEMP ⁺ to TEMP ⁻ | 0.598 | V |
|----------------------|-------------------------|---|-------|-------|
| TC | Temperature Coefficient | | -2.0 | mV/°C |

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LTM4636-1 is tested under pulsed load conditions such that $T_J \approx T_A$. The LTM4636-1E is guaranteed to meet performance specifications over the 0°C to 125°C internal operating temperature range. Specifications over the full -40°C to 125°C internal operating temperature range are assured by design, characterization and correlation with statistical process controls. The LTM4636-11 is guaranteed to meet specifications over the full -40°C to 125°C internal operating temperature

range. Note that the maximum ambient temperature consistent with these specifications is determined by specific operating conditions in conjunction with board layout, the rated package thermal resistance and other environmental factors.

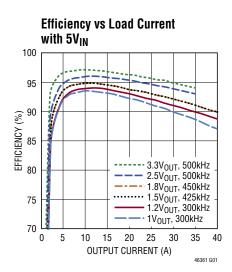
Note 3: The minimum on-time condition is specified for a peak-to-peak inductor ripple current of ~40% of I_{MAX} Load. (See the Applications Information section)

Note 4: See output current derating curves for different V_{IN} , V_{OUT} and T_A .

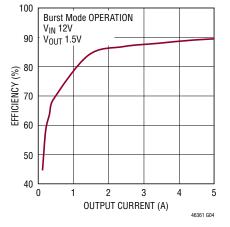
Note 5: Guaranteed by design.

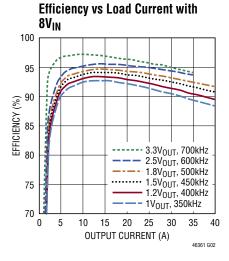
Note 6: 100% tested at wafer level.

TYPICAL PERFORMANCE CHARACTERISTICS



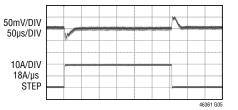
Burst Mode Efficiency vs Load Current





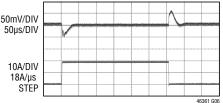
Efficiency vs Load Current with 12V_{IN} 100 95 14.14 ----EFFICIENCY (%) 82 80 80 90 3.3V_{OUT}, 750kHz 2.5V_{OUT}, 650kHz —- 1.8V_{OUT}, 600kHz 1.5V_{OUT}, 550kHz 1.2V_{OUT}, 400kHz 1.2V_{OUT}, 350kHz 75 70 0 5 10 15 20 25 30 35 40 OUTPUT CURRENT (A) 46361 G03

1V Transient Response

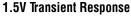


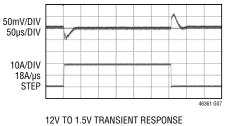
12V T0 1V TRANSIENT RESPONSE C_{0UT} = 4 \times 100 μ F CERAMIC, 3 \times 470 μ F 2.5V POSCAP 5m Ω C_{FF} = 22 pF, SW FREQ = 400 kHz

1.2V Transient Response



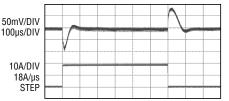
12V TO 1.2V TRANSIENT RESPONSE $\begin{array}{l} C_{OUT}=4\times100\mu F \mbox{ CERAMIC}, 3\times470\mu F 2.5V \\ \mbox{POSCAP } 5m\Omega \\ \mbox{C}_{FF}=22\rho F, \mbox{SW FREQ}=400 \mbox{Hz} \\ \mbox{C}_{COMP}=100 \mbox{pF} \end{array}$





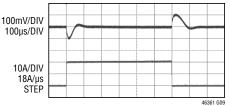
 $\begin{array}{l} 120\ \text{O}\ \text{I}.50\ \text{I}\text{AMSENT}\ \text{ResPONSE}\\ \text{C}_{\text{OUT}}=4\times100\mu\text{F}\ \text{CERAMIC}, 3\times470\mu\text{F}\ 2.5V\\ \text{POSCAP}\ \text{5m}\Omega\\ \text{C}_{\text{FF}}=22p\text{F}\ \text{SW}\ \text{FREQ}=425\text{kHz}\\ \text{C}_{\text{COMP}}=100p\text{F} \end{array}$





12V TO 1.8V TRANSIENT RESPONSE $C_{OUT} = 6 \times 100 \mu F$ CERAMIC, 2 × 470 μF 4V POSCAP 5m Ω $C_{FF} = 22 pF$, SW FREQ = 500 kHz $C_{COMP} = 100 pF$



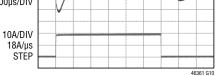


12V TO 2.5V TRANSIENT RESPONSE $C_{OUT} = 6 \times 100 \mu F$ CERAMIC, 2 × 470 μ F 4V POSCAP 5m Ω $C_{FF} = 22 p F$, SW FREQ = 650 kHz $C_{COMP} = 100 p F$

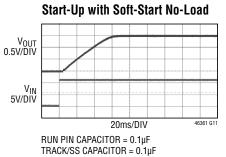


TYPICAL PERFORMANCE CHARACTERISTICS

3.3V Transient Response

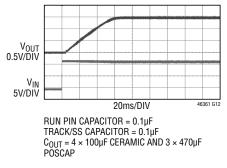


12V TO 3.3V TRANSIENT RESPONSE C_{OUT} = 6 × 100µF CERAMIC, 2 × 470µF 4V POSCAP 5m Ω C_{FF} = 22pF, SW FREQ = 750kHz C_{COMP} = 100pF

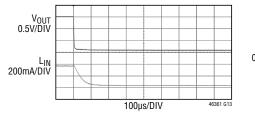


TRACK/SS CAPACITOR = 0.1 μ F C_{OUT} = 4 × 100 μ F CERAMIC AND 3 × 470 μ F POSCAP

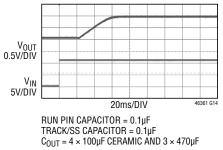
Start-Up with Soft-Start Full Load



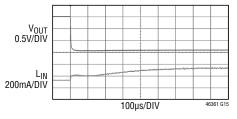
40A Load Short-Circuit



Start-Up with 0.5V Output Pre-Bias



No-Load Short-Circuit



PIN FUNCTIONS



PACKAGE ROW AND COLUMN LABELING MAY VARY AMONG µModule PRODUCTS. REVIEW EACH PACKAGE LAYOUT CAREFULLY.

V_{OUT} (A1-A12, B1-B12, C1-C12, D1-D2, D11-D12): Power Output Pins. Apply output load between these pins and GND pins. Recommend placing output decoupling capacitance between these pins and GND pins. Review Table 4.

MODE_PLLIN (H3): Forced Continuous Mode, Burst Mode Operation, or Pulse-Skipping Mode Selection Pin and External Synchronization Input to Phase Detector Pin. Connect this pin to $INTV_{CC}$ to enable pulse-skipping mode of operation. Connect to ground to enable forced continuous mode of operation. Floating this pin will enable Burst Mode operation. A clock on this pin will enable synchronization with forced continuous operation. See the Applications Information section.

V_{OUTS1}⁻ (D3): V_{OUT} Sense Ground for the Remote Sense Amplifier. This pin connects to the ground remote sense point. Connect to ground when not used. See the Applications Information section.

 V_{OUTS1} ⁺ (D4): This pin should connect to V_{OUT} and is connected to V_{FB} through a 4.99k resistor. This pin is used to connect to a remote sense point of the load for accurate voltage sensing. Either connect to remote sense point or directly to V_{OUT} . See the Applications Information section for details.

COMPB (D5): Internal compensation network provided that coincides with proper stability utilizing the values in Table 5. Just connect this pin to COMPA for internal compensation. In parallel operation with other LTM4636-1 devices, connect COMPA and COMPB pins together for internal compensation, then connect all COMPA pins together.

GND (D6-D9, E6-E9, F7, F8, F10, F12, G1-G2, G6 G10, H1, H10-H12, J1-J3, J8-J12, K1-K3, K9-K10, K12, L1-L3, L9-L10, L12, M1-M3, M9-M12): Ground Pins for Both Input and Output Returns.

PGOOD (E1): Output Voltage Power Good Indicator. Opendrain logic output is pulled to ground when the output voltage exceeds a $\pm 7.5\%$ regulation window.

RUNC (E2): Run Control Pin. A voltage above 1.35V will turn on the control section of the module. A 10k resistor

to ground is internal to the module for setting the RUN pin threshold with a resistor to 5V, and allowing a pullup resistor to PV_{CC} for enabling the device. See Figure 1 Block Diagram.

TRACK/SS (E3): Output Voltage Tracking Pin and Soft-Start Inputs. The pin has a 1.25 μ A pull-up current source. A capacitor from this pin to ground will set a soft-start ramp rate. In tracking, the regulator output can be tracked to a different voltage. The different voltage is applied to a voltage divider then to the slave output's track pin. This voltage divider is equal to the slave output's feedback divider for coincidental tracking. Default soft-start of 750 μ s with TRACK/SS pin connected to INTV_{CC} pin. See the Applications Information section. In PolyPhase[®] applications tie the TRACK/SS pins together.

 V_{FB} (E4): The Negative Input of the Error Amplifier. Internally, this pin is connected to V_{OUTS1} with a 4.99k precision resistor. Different output voltages can be programmed with an additional resistor between V_{FB} and V_{OSNS} ⁻. In PolyPhase operation, tying the V_{FB} pins together allows for parallel operation. See the Applications Information section.

COMPA (E5): Current Control Threshold and Error Amplifier Compensation Point. The current comparator threshold increases with this control voltage. Tie all COMPA pins together for parallel operation. This pin allows external compensation. See the Applications Information section.

OVP_TRIP (E10): This open-drain pin can be used to trip off and retry an input circuit breaker or alert the system to an output overvoltage programmed on the OVP_SET pin. See the Applications Information section.

CROWBAR (E11): This pin can be optionally used to clamp the output voltage in an overvoltage condition to protect the load to tighter control of overvoltage. See the Applications Information section.

SNSP2 (F1): Current Sense Signal Path. Connect this pin to SNSP1 (F2).

SNSP1 (F2): Current Sense Signal Path. Connect this pin to SNSP2 (F1). Both pins are used to calibrate current sense matching and current limit at final test.

PIN FUNCTIONS

HIZREG (F3): When this pin is pulled low the power stage is disabled into high impedance. Tie this pin to V_{IN} or INTV_{CC} for normal operation.

OVER_TEMP (D10): This overtemperature protection is programmable with an internal monitor that is referenced to the TMON pin and the OTP_SET pin. The OVER_TEMP pin can be used to alert the system if the module regulator overheats, and this signal can be used to trip off and retry an electronic circuit breaker in a fault condition. The pin is an open collector that pulls active low in response to OVER_TEMP. The OVER_TEMP pin can be left floating if not used. See the Applications Information section for details.

SGND (F4, G4): Signal Ground Pin. Return ground path for all analog and low power circuitry. Tie a single connection to the output capacitor GND in the application. See layout guidelines in Figure 18.

INTV_{CC} (F6): Internal 5.5V LDO for Driving the Control Circuitry in the LTM4636-1. INTV_{CC} is controlled and enabled when RUNC is activated high.

FREQ (G5): A resistor can be applied from this pin to ground to set the operating frequency. This pin sources 20µA. See the Applications Information section.

PHMODE (G7): This pin can be voltage programmed to change the phase relationship of the CLKOUT pin with reference to the internal clock or an input synchronized clock. The $INTV_{CC}$ (5.5V) output can be voltage divided down to the PHASMD pin to set the particular phase. The Electrical Characteristics show the different settings to select a particular phase. See the Applications Information section.

RUNP (G8): This pin enables the PV_{CC} supply. This pin can be connected to V_{IN}, or tie to ground when connecting PV_{CC} to V_{IN} \leq 5.5V. RUNP needs to sequence up before RUNC. A 15k resistor from PV_{CC} to RUNC with a 0.1µF capacitor will provide enough delay. In parallel operation with multiple LTM4636-1s, the resistor can be reduced in value by N times and the 0.1µF can be increased N times. See Applications Information section. RUNP can be used to set the minimum UVLO with a voltage divider. See Figure 1.

PV_{CC} (F9): 5V Power Output and Power for Internal Power MOSFET Drivers. The regulator can power 50mA of external sourcing for additional use. Place a 22μ F ceramic filter capacitor on this pin to ground. When V_{IN} < 5.5V, tie V_{IN} and PV_{CC} together. Then tie RUNP to GND. If $V_{IN} > 5.5V$ then operate PV_{CC} regulator as normal. See the Typical Application examples.

OVP_SET (E12): This pin is used to set the output overvoltage trip point. This pin has a $24.9 k\Omega$ resistor on it to ground. See the Applications Information section. Float is not used.

BIAS (G9): This pin is used to power the OTP and OVP circuitry independently of the main power feed. See the Applications Information section.

TEMP⁺ (G12): Temperature Monitor. An internal diode connected NPN transistor. See the Applications Information section.

OTP_SET (F11): This pin is used to set the overtemperature set point. The pin has a 24.9k resistor on it to ground. See Applications Information section. Float if not used.

TEMP⁻ (G11): Low Side of the Internal Temperature Monitor.

CLKOUT (G3): Clock out signal that can be phase selected to the main internal clock or synchronized clock using the PHASMD pin. CLKOUT can be used for multiphase applications. See the Applications Information section.

TEST1 (H4), TEST2 (F5), TEST3 (H2), GMON (H9):These are test pins used in the final production test of the part. Leave floating.

 V_{IN} (H5-H6, J4-J7, K4-K8, L4-L8, M4-M8): Power Input Pins. Apply input voltage between these pins and GND pins. Recommend placing input decoupling capacitance directly between V_{IN} and GND pins.

PWM (H7): PWM output that drives the power stage. Primarily used for test, but can be monitored in debug or testing.

TMON (H8): Temperature Monitor Pin. Internal temperature monitor, varies from 1.0V at 25° C to 1.44V at 150° C, disables power stage at >150°C. The OTP_Trip signal is set to trip off at a value lower than 150°C. If the temperature monitor feature is not desired, then tie the TMON pin to GND.

SW (L11, K11): These are pin connections to the internal switch node for test evaluation and monitoring. An R-C snubber can be placed from the switch pins to GND to eliminate any high frequency ringing. See the Applications Information section.

BLOCK DIAGRAM

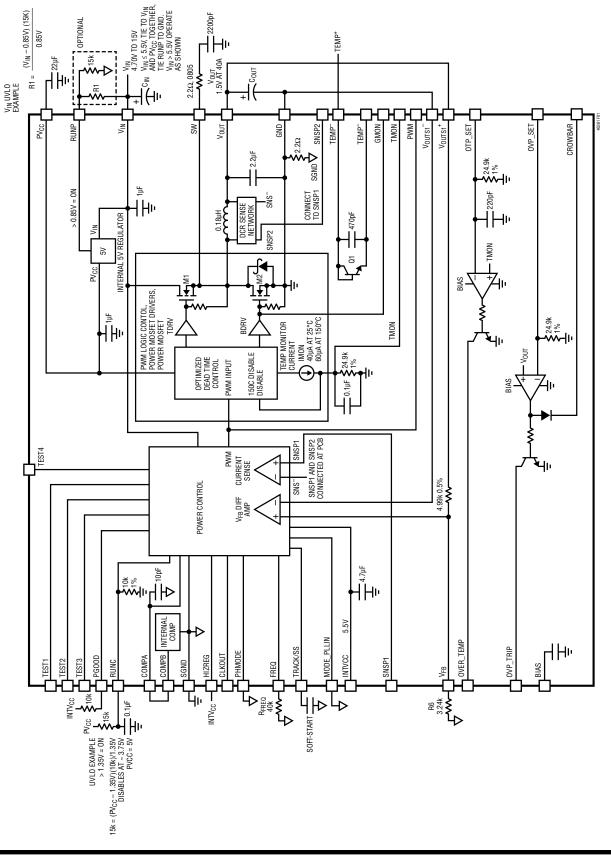


Figure 1. Simplified LTM4636-1 Block Diagram

DECOUPLING REQUIREMENTS $T_A = 25^{\circ}C$. Use Figure 1 configuration.

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNITS |
|------------------|--|--|-----|------|-----|-------|
| C _{IN} | External Input Capacitor Requirement $(V_{IN} = 4.70V \text{ to } 16V, V_{OUT} = 1.5V)$ | I_{OUT} = 40A, 6 × 22µF Ceramic X7R Capacitors (See Table 4) | 100 | | | μF |
| C _{OUT} | External Output Capacitor Requirement (V _{IN} = 4.70V to 16V, V _{OUT} = 1.5V) | I _{OUT} = 40A (See Table 4) | | 1000 | | μF |

OPERATION

Power Module Description

The LTM4636-1 is a high efficiency regulator that can provide a 40A output with few external input and output capacitors. This module provides precisely regulated output voltages programmable via external resistors from 0.6V DC to 3.3V DC over a 4.70V to 15V input range. The Typical Application schematic with protection is shown in Figure 20.

The LTM4636-1 has an integrated constant-frequency current mode regulator, power MOSFETs, 0.18µH inductor, protection circuitry, 5V regulator and other supporting discrete components. The switching frequency range is from 250kHz to 770kHz, and the typical operating frequency is 400kHz. For switching noise-sensitive applications, it can be externally synchronized from 250kHz to 800kHz, subject to minimum on-time limitations and limiting the inductor ripple current to less than 40% of maximum output current.

A single resistor is used to program the frequency. See the Applications Information section.

With current mode control and internal feedback loop compensation, the LTM4636-1 module has sufficient stability margins and good transient performance with a wide range of output capacitors, even with all ceramic output capacitors. An option has been provided for external loop compensation. LTpowerCAD[™] can be used to optimize the external compensation option. See the Applications Information section.

Current mode control provides cycle-by-cycle fast current limit in an overcurrent condition. An internal overvoltage monitor feedback pin referred will attempt to protect the output voltage in the event of an overvoltage >10%. The top MOSFET is turned off and the bottom MOSFET is turned on until the output is cleared. Pulling the RUNC pin below 1.1V forces the regulator controller into a shutdown state. The TRACK/SS pin is used for programming the output voltage ramp and voltage tracking during start-up. See the Applications Information section.

Optional internal overvoltage protection and overtemperature functions can be used to protect from power MOSFET failures, input and output overvoltage and overtemperature conditions. These two features can be used to trip off and retry an input circuit breaker in the event of either/or both an overvoltage and overtemperature fault. The OVP_TRIP, OVER_TEMP, TMON, OVP_SET, CROWBAR and OTP_SET pins are all used to support these two features. These features can be implemented along with an input circuit breaker to protect expensive systems boards, processors and FPGA devices from damage. See the Applications Information section.

The LTM4636-1 is internally compensated to be stable over all operating conditions. Table 5 provides a guideline for input and output capacitances for several operating conditions. LTpowerCAD is available for transient and stability analysis. This tool can be used to optimize the regulators loop response.

A remote sense amplifier is provided for accurately sensing output voltages at the load point.

Multiphase operation can be easily employed with the internal clock source or a synchronization clock applied to the MODE/PLLIN input using an external clock source, and connecting the CLKOUT pins. See the Applications Information section. Review Figure 4.

High efficiency at light loads can be accomplished with selectable Burst Mode operation using the MODE_PLLIN pin. These light load features will accommodate battery operation. Efficiency graphs are provided for light load operation in the Typical Performance Characteristics section.

OPERATION

A TEMP⁺ and TEMP⁻ pins are provided to allow the internal device temperature to be monitored using an onboard diode connected NPN transistor.

High efficiency at light loads can be accomplished with selectable Burst Mode operation using the MODE_PLLIN pin. These light load features will accommodate battery operation. Efficiency graphs are provided for light load operation in the Typical Performance Characteristics section.

APPLICATIONS INFORMATION

The typical LTM4636-1 application circuit is shown in Figure 20. External component selection is primarily determined by the maximum load current and output voltage. Refer to Table 5 for specific external capacitor requirements for particular applications.

V_{IN} to V_{OUT} Step-Down Ratios

There are restrictions in the V_{IN} to V_{OUT} step-down ratio that can be achieved for a given input voltage. The maximum duty cycle is 94% typical at 500kHz operation. The V_{IN} to V_{OUT} minimum dropout is a function of load current and operation at very low input voltage and high duty cycle applications. At very low duty cycles the minimum 100ns on-time must be maintained. See the PLL, Frequency Adjustment and Synchronization section and temperature derating curves.

Output Voltage Programming

The PWM controller has an internal 0.6V $\pm 1\%$ reference voltage. As shown in the Block Diagram, a 4.99k internal feedback resistor connects the V_{OUTS1} and V_{FB} pins together. When the remote sensing is used, then V_{OUTS1}⁺ and V_{OUTS1}⁻ are connected to the remote V_{OUT} and GND points. If no remote sense the V_{OUTS1}⁺ connects to V_{OUT}. The output voltage will default to 0.6V with no feedback resistor. Adding a resistor R_{FB} from V_{FB} to ground programs the output voltage:

$$V_{OUT} = 0.6 V \bullet \frac{4.99 k + R_{FB}}{R_{FB}}$$

Table 1. V_{FB} Resistor Table vs Various Output Voltages

| V _{OUT} (V) | 0.6 | 1.0 | 1.2 | 1.5 | 1.8 | 2.5 | 3.3 |
|----------------------|------|-----|------|------|------|------|-----|
| R _{FB} (k) | Open | 7.5 | 4.99 | 3.24 | 2.49 | 1.58 | 1.1 |

For parallel operation of N LTM4636-1s, the following equation can be used to solve for R_{FB} :

$$R_{FB} = \frac{4.99 \text{ k/N}}{\frac{\text{V}_{OUT}}{0.6 \text{ V}} - 1}$$

Or use V_{OUTS1} on one channel and connect all feedback pins together utilizing a single feedback resistor.

Tie the V_{FB} pins together for each parallel output. The COMP pins must be tied together also. See the Typical Applications section examples.

Input Capacitors

The LTM4636-1 module should be connected to a low AC-impedance DC source. Additional input capacitors are needed for the RMS input ripple current rating. The $I_{CIN(RMS)}$ equation which follows can be used to calculate the input capacitor requirement. Typically 22µF X7R ceramics are a good choice with RMS ripple current ratings of ~4A each. A 47µF to 100µF surface mount aluminum electrolytic bulk capacitor can be used for more input bulk capacitance. This bulk input capacitor is only needed if the input source impedance is compromised by long inductive leads, traces or not enough source capacitance. If low impedance power planes are used, then this bulk capacitor is not needed.

For a buck converter, the switching duty cycle can be estimated as:

$$\mathsf{D} = \frac{\mathsf{V}_{\mathsf{OUT}}}{\mathsf{V}_{\mathsf{IN}}}$$

Without considering the inductor ripple current, for each output the RMS current of the input capacitor can be estimated as:

 $I_{CIN(RMS)} = \frac{I_{OUT(MAX)}}{\eta\%} \bullet \sqrt{D \bullet (1-D)}$

where $\eta\%$ is the estimated efficiency of the power module. The bulk capacitor can be a switcher-rated aluminum electrolytic capacitor or a Polymer capacitor.

Output Capacitors

The LTM4636-1 is designed for low output voltage ripple noise. The bulk output capacitors defined as C_{OUT} are chosen with low enough effective series resistance (ESR) to meet the output voltage ripple and transient requirements. C_{OUT} can be a low ESR tantalum capacitor, low ESR Polymer capacitor or ceramic capacitors. The typical output capacitance range is from 400µF to 1000µF. Additional output filtering may be required by the system designer if further reduction of output ripple or dynamic transient spikes is required. Table 5 shows a matrix of different output voltages and output capacitors to minimize the voltage droop and overshoot during a 15A/µs transient. The table optimizes total equivalent ESR and total bulk capacitance to optimize the transient performance. Stability criteria are considered in the Table 5 matrix, and LTpowerCAD is available for stability analysis. Multiphase operation will reduce effective output ripple as a function of the number of phases. Application Note 77 discusses this noise reduction versus output ripple current cancellation, but the output capacitance should be considered carefully as a function of stability and transient response. LTpowerCAD can be used to calculate the output ripple reduction as the number of implemented phases increases by N times. External loop compensation can be used for transient response optimization.

Burst Mode Operation

The LTM4636-1 is capable of Burst Mode operation in which the power MOSFETs operate intermittently based on load demand, thus saving quiescent current. For applications where maximizing the efficiency at very light loads is a high priority, Burst Mode operation should be applied. To enable Burst Mode operation, simply float the MODE_PLLIN pin. During Burst Mode operation, the peak current of the inductor is set to approximately 30% of the maximum peak current value in normal operation even though the voltage at the COMPA pin indicates a lower value. The voltage at the COMPA pin drops when the inductor's average current is greater than the load requirement. As the COMPA voltage drops below 0.5V, the burst comparator trips, causing the internal sleep line to go high and turn off both power MOSFETs.

In sleep mode, the internal circuitry is partially turned off, reducing the quiescent current. The load current is now being supplied from the output capacitors. When the output voltage drops, causing COMPA to rise, the internal sleep line goes low, and the LTM4636-1 resumes normal operation. The next oscillator cycle will turn on the top power MOSFET and the switching cycle repeats.

Pulse-Skipping Mode Operation

In applications where low output ripple and high efficiency at intermediate currents are desired, pulse-skipping mode should be used. Pulse-skipping operation allows the LTM4636-1 to skip cycles at low output loads, thus increasing efficiency by reducing switching loss. Tying the MODE_PLLIN pin to INTV_{CC} enables pulse-skipping operation. With pulse-skipping mode at light load, the internal current comparator may remain tripped for several cycles, thus skipping operation cycles. This mode has lower ripple than Burst Mode operation and maintains a higher frequency operation than Burst Mode operation.

Forced Continuous Operation

In applications where fixed frequency operation is more critical than low current efficiency, and where the lowest output ripple is desired, forced continuous operation should be used. Forced continuous operation can be enabled by tying the MODE_PLLIN pin to ground. In this mode, inductor current is allowed to reverse during low output loads, the COMPA voltage is in control of the current comparator threshold throughout, and the top MOSFET always turns on with each oscillator pulse. During start-up, forced continuous mode is disabled and inductor current is prevented from reversing until the LTM4636-1's output voltage is in regulation.

Multiphase Operation

For outputs that demand more than 40A of load current, multiple LTM4636-1 devices can be paralleled to provide more output current without increasing input and output ripple voltage. The MODE_PLLIN pin allows the LTM4636-1 to be synchronized to an external clock and the internal phase-locked loop allows the LTM4636-1 to lock onto input clock phase as well. The FREQ resistor is selected for normal frequency, then the incoming clock can synchronize the device over the specified range.

A multiphase power supply significantly reduces the amount of ripple current in both the input and output capacitors. The RMS input ripple current is reduced by, and the effective ripple frequency is multiplied by, the number of phases used (assuming that the input voltage is greater than the number of phases used times the output voltage). The output ripple amplitude is also reduced by the number of phases used. See Application Note 77.

The LTM4636-1 device is an inherently current mode controlled device, so parallel modules will have good current sharing. This will balance the thermals in the design.

Tie the COMPA to COMPB and then tie the COMPA pins together, tie V_{FB} pins of each LTM4636-1 together to share the current evenly. Figure 21 shows a schematic of the parallel design. For external compensation and parallel operation only tie COMP A pins together with external compensation.

Input RMS Ripple Current Cancellation

Application Note 77 provides a detailed explanation of multiphase operation. The input RMS ripple current cancellation mathematical derivations are presented, and a graph is displayed representing the RMS ripple current reduction as a function of the number of interleaved phases (see Figure 2).

PLL, Frequency Adjustment and Synchronization

The LTM4636-1 switching frequency is set by a resistor (R_{FREQ}) from the FREQ pin to signal ground. A 20µA current (I_{FREQ}) flowing out of the FREQ pin through R_{FREQ} develops a voltage on the FREQ pin. R_{FREQ} can be calculated as:

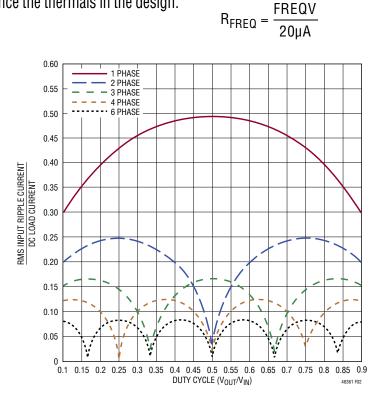


Figure 2. Normalized Input RMS Ripple Current vs Duty Cycle for One to Six µModule Regulators (Phases)

The relationship of FREQV voltage to switching frequency is shown in Figure 3. For low output voltages from 0.6V to 1.2V, 350kHz operation is an optimal frequency for the best power conversion efficiency while maintaining the inductor current to about 45% of maximum load current. For output voltages from 1.5V to 1.8V, 500kHz is optimal. For output voltages from 2.5V to 3.3V, 700kHz is optimal. See efficiency graphs for optimal frequency set point. Limit the 2.5V and 3.3V outputs to 35A.

The LTM4636-1 can be synchronized from 200kHz to 1200kHz with an input clock that has a high level above 2V and a low level below 1.2V. See the Typical Applications section for synchronization examples. The LTM4636-1 minimum on-time is limited to approximately 100ns. The on-time can be calculated as:

$$t_{ON(MIN)} = \frac{1}{FREQ} \cdot \left(\frac{V_{OUT}}{V_{IN}}\right)$$

The LTM4636-1's CLKOUT pin phase difference from V_{OUT} can be programmed by applying a voltage to the PHMODE pin. This voltage can be programmed using the 5.5V INTV_{CC} pin. Most of the phase selections can be programmed by either grounding, floating, or tying this pin to INTV_{CC}. The 60 degree phase shift will require 3/4 INTV_{CC} and can be programmed with a voltage divider from the INTV_{CC} pin. See Figure 4 for phase programming and the 2 to 6 phase connections. See Figure 21 for example design.

Output Voltage Tracking

Output voltage tracking can be programmed externally using the TRACK/SS pin. The output can be tracked up and down with another regulator. The master regulator's output is divided down with an external resistor divider that is the same as the slave regulator's feedback divider to implement coincident tracking. The LTM4636-1 uses

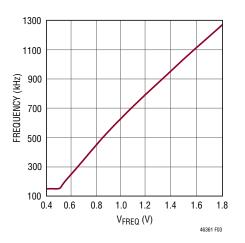


Figure 3. FREQ Voltage to Switching Frequency

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an accurate 4.99k resistor internally for the top feedback resistor. Figure 5 shows an example of coincident tracking.

$$V_{OUT(SLAVE)} = \left(1 + \frac{4.99k}{R_{TA}}\right) \bullet V_{TRACK}$$

 V_{TRACK} is the track ramp applied to the slave's track pin. V_{TRACK} has a control range of 0V to 0.6V, or the internal reference voltage. When the master's output is divided down with the same resistor values used to set the slave's output, then the slave will coincident track with the master until it reaches its final value. The master will continue to its final value from the slave's regulation point (see Figure 6). Voltage tracking is disabled when V_{TRACK} is more than 0.6V. R_{TA} in Figure 5 will be equal to R_{FB} for coincident tracking.

The TRACK/SS pin of the master can be controlled by an external ramp or the soft-start function of that regulator can be used to develop that master ramp. The LTM4636-1 can be used as a master by setting the ramp rate on its track pin using a soft-start capacitor. A 1.25μ A current source is used to charge the soft-start capacitor. The following equation can be used:

$$t_{\text{SOFT-START}} = 0.6V \bullet \left(\frac{C_{\text{SS}}}{1.25 \mu \text{A}}\right)$$

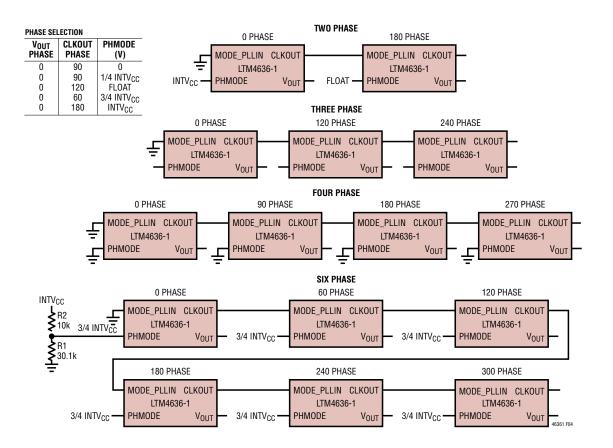
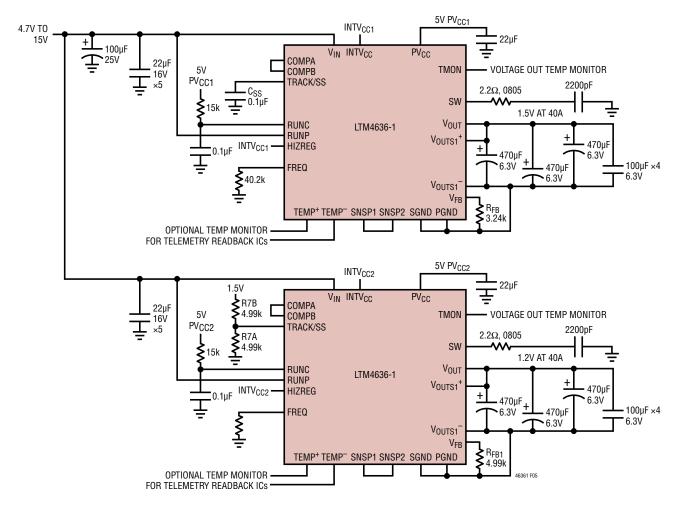
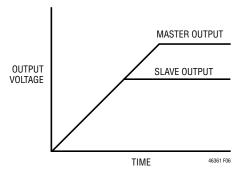


Figure 4. Phase Selection Examples



PINS NOT USED IN THIS CIRCUIT: CLKOUT, GMON, MODE/PLLIN, PGOOD, OTP_SET, CROWBAR, OVP_TRIP, OVP_SET, BIAS, OVER_TEMP, PHMODE, PWM, TEST1, TEST2, TEST3

Figure 5. Dual Outputs (1.5V and 1.2V) with Tracking





Ratiometric tracking can be achieved by a few simple calculations and the slew rate value applied to the master's TRACK/SS pin. As mentioned above, the TRACK/SS pin has a control range from OV to 0.6V. The master's TRACK/SS pin slew rate is directly equal to the master's output slew rate in volts/time. The equation:

$$\frac{MR}{SR} \bullet 4.99k = R_{TB}$$

where MR is the master's output slew rate and SR is the slave's output slew rate in volts/time. When coincident tracking is desired, then MR and SR are equal, thus R_{TB} is equal to 60.4k. R_{TA} is derived from equation:

$$R_{TA} = \frac{0.6V}{\frac{V_{FB}}{4.99k} + \frac{V_{FB}}{R_{FB1}} - \frac{V_{TRACK}}{R_{TB}}}$$

where V_{FB} is the feedback voltage reference of the regulator, and V_{TRACK} is 0.6V. Since R_{TB} is equal to the 4.99k top feedback resistor of the slave regulator in equal slew rate or coincident tracking, then R_{TA} is equal to R_{FB} with V_{FB} = V_{TRACK}. Therefore R_{TB} = 4.99k, and R_{TA} = 4.99k in Figure 5.

In ratiometric tracking, a different slew rate maybe desired for the slave regulator. R_{TB} can be solved for when SR is slower than MR. Make sure that the slave supply slew rate is chosen to be fast enough so that the slave output voltage will reach its final value before the master output.

For example, MR = 1.5V/ms, and SR = 1.2V/ms. Then R_{TB} = 6.19k. Solve for R_{TA} to equal 4.22k.

For applications that do not require tracking or sequencing, simply tie the TRACK/SS pin to $\rm INTV_{CC}$ to let RUN control the turn on/off. When the RUN pin is below its threshold or the V_{IN} undervoltage lockout, then TRACK/SS is pulled low.

Default Overcurrent and Overvoltage Protection

The LTM4636-1 has overcurrent protection (OCP) in a short circuit. The internal current comparator threshold folds back during a short to reduce the output current. An overvoltage condition (OVP) above 10% of the regulated

output voltage will force the top MOSFET off and the bottom MOSFET on until the condition is cleared. Foldback current limiting is disabled during soft-start or tracking start-up.

Temperature Monitoring

Measuring the absolute temperature of a diode is possible due to the relationship between current, voltage and temperature described by the classic diode equation:

$$I_{D} = I_{S} \bullet e\left(\frac{V_{D}}{\eta \bullet V_{T}}\right)$$

or
$$V_{D} = \eta \bullet V_{T} \bullet \ln \frac{I_{D}}{I_{S}}$$

where I_D is the diode current, V_D is the diode voltage, η is the ideality factor (typically close to 1.0) and I_S (saturation current) is a process dependent parameter. V_T can be broken out to:

$$V_{T} = \frac{k \bullet T}{q}$$

where T is the diode junction temperature in Kelvin, q is the electron charge and k is Boltzmann's constant. V_T is approximately 26mV at room temperature (298K) and scales linearly with Kelvin temperature. It is this linear temperature relationship that makes diodes suitable temperature sensors. The I_S term in the previous equation is the extrapolated current through a diode junction when the diode has zero volts across the terminals. The I_S term varies from process to process, varies with temperature, and by definition must always be less than I_D. Combining all of the constants into one term:

$$K_{\rm D} = \frac{\eta \bullet k}{q}$$

where $K_D = 8.62^{-5}$, and knowing $ln(l_D/l_S)$ is always positive because l_D is always greater than l_S , leaves us with the equation that:

$$V_{D} = T(KELVIN) \bullet K_{D} \bullet In \frac{I_{D}}{I_{S}}$$

where V_D appears to increase with temperature. It is common knowledge that a silicon diode biased with a current source has an approximate $-2mV/^\circ C$ temperature relationship (Figure 7), which is at odds with the equation. In fact, the I_S term increases with temperature, reducing the $ln(I_D/I_S)$ absolute value yielding an approximate $-2mV/^\circ C$ composite diode voltage slope.

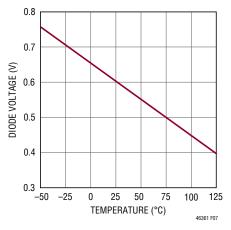


Figure 7. Diode Voltage V_D vs Temperature T(°C)

To obtain a linear voltage proportional to temperature we cancel the I_S variable in the natural logarithm term to remove the I_S dependency from the equation 1. This is accomplished by measuring the diode voltage at two currents I_1 , and I_2 , where $I_1 = 10 \cdot I_2$) and subtracting we get:

$$\Delta V_{\rm D} = T(\text{KELVIN}) \bullet K_{\rm D} \bullet \text{IN} \frac{I_1}{I_{\rm S}} - T(\text{KELVIN}) \bullet K_{\rm D} \bullet \text{IN} \frac{I_2}{I_{\rm S}}$$

Combining like terms, then simplifying the natural log terms yields:

$$\Delta V_{\rm D} = T(\text{KELVIN}) \bullet K_{\rm D} \bullet \text{IN}(10)$$

and redefining constant

$$K_{\rm D}^{\rm '} = K_{\rm D} \bullet {\rm IN}(10) = \frac{198\mu V}{K}$$

yields

$$\Delta V_{\rm D} = K'_{\rm D} \bullet T(\text{KELVIN})$$

Solving for temperature:

$$T(KELVIN) = \frac{\Delta V_D}{K'_D} (°CELSIUS) = T(KELVIN) - 273.15$$

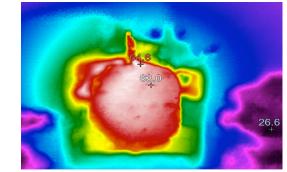
where

300°K = 27°C

means that is we take the difference in voltage across the diode measured at two currents with a ratio of 10, the resulting voltage is 198μ V per Kelvin of the junction with a zero intercept at 0 Kelvin.

The diode connected NPN transistor at the TEMP pin can be used to monitor the internal temperature of the LTM4636-1.

| V _{IN} | V _{OUT} | I _{OUT} | AIR FLOW |
|-----------------|------------------|------------------|----------|
| 12 | 1 | 40 | 200 LFM |



(8a)

| V _{IN} V _{OUT} | | I _{OUT} | AIR FLOW | |
|----------------------------------|-----|------------------|----------|--|
| 12 | 3.3 | 35 | 200 LFM | |

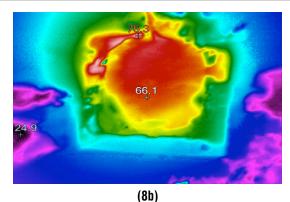


Figure 8. The Two Images Show the LTM4636-1 Operating at 1V at 40A and 3.3V at 35A from a 12V Input. Both Images Reflect Only a 40°C to 45°C Rise Above Ambient at Full Load Current with 200LPM

Enhanced Overvoltage OVP and Overtemperature Protection OTP

The LTM4636-1 has two enhanced protection features that can be used to detect overtemperature and overvoltage.

The BIAS pin is supplied to power the protection circuitry off of an auxiliary supervisory supply separate from the high power circuit breaker path. This is required to properly bias the protection circuitry with the proper headroom at power up, and circuit breaker retry. This separate bias supply needs to supply 1mA per module, and 6mA per module during an overvoltage and overtemperature event. If the CROWBAR signal is used then an instantaneous current will be need to drive the crow bar mosfets. This is current is ~ 50mA. The bias voltage can be used to program the OTP and OVP set points.

The TMON pin voltage varies from 1.0V at 25°C up to 1.45V at 150°C. The TMON pin can be compared to a programmable set point utilizing the 24.9k resistor to ground on the OTP_SET pin. See the block diagram. By adding an external resistor from this pin to the BIAS pin, an OTP trip point can be set below the 150°C (1.45V) level as an overtemperature detection, and the OVER_TEMP opencollector pin will pull low to provide a system alert, or can be used to trip off power. This feature can be ignored by floating the OVER_TEMP and OTP_SET pins.

The equation:

 $R_{OTP} = 24.9k \bullet \left[\left(\frac{BIAS}{OTP_SET} \right) - 1 \right];$ OTP_SET = 1.0V(25°C) + 3.52mV/°C • 105°C

For 130°C, OTP_SET = 1.37V

Where BIAS is the voltage applied to BIAS pin, Ex: 5V. OTP_SET is the voltage equivalent to temperature on the TMON pin. For example, BIAS = 5V, and the overtemperature trip point is set to 130°C. TMON has a range of 440mV from 25°C to 150°C, therefore the TMON pin moves $3.52mV/^{\circ}C$ above 25°C. 130°C minus 25°C = 105°C rise.

The ROTP resistor calculates out to a close 1% value of 66.5k.

The BIAS supply can be between 4V to 5.5V, the OTP_SET trip point depends on the BIAS supply voltage to be accurate, otherwise a more accurate reference can be derived from the BIAS supply to be utilized to program the set point. See application schematics.

The LTM4636-1 controller has overvoltage protection feedback voltage referred that trips at ~7.5% above V_{OUT} . This feature will try to correct an overvoltage transient issue, but does not protect for a shorted input power source in the event of a top power switch short while the bottom switch is on trying to protect the load. The input source has a direct path to ground in this condition. Neither will this feature protect an overvoltage issue caused by an open feedback path. The enhanced overvoltage protection consists of a fast comparator that compares V_{OUT} to a programmed value set at the OVP_SET pin. An OVP_TRIP point can be set using the BIAS supply and an external resistor (R_{OVP}) with the internal 24.9k resistor. The equation:

$$R_{OVP} = 24.9k \bullet \left[\left(\frac{BIAS}{OVP_TRIP} \right) - 1 \right]$$

where OVP TRIP is the maximum overvoltage level set point. The OVP_TRIP open-collector output pulls low and can be used to trip off a circuit breaker or alert the system of an OVP fault. The CROWBAR output drive can be used to drive an external N-channel power MOSFET to clamp the output voltage and discharge the inductor stored energy. Depending on the power design, the OVP trip point and the output capacitance, the CROWBAR clamp may not be needed. Testing will need to be performed to characterize the behavior of the clamping with and without the crowbar. Proper crowbar power MOSFET SOA (safe operating area) selection will be required to make sure the MOSFET can handle the discharge current. A small surface mount resistor can be placed in series from V_{OUT} to the drain of the CROWBAR FET to limit the CROWBAR but still clamp the output. To disable the function, float the OVP_SET, OVP_TRIP and CROWBAR pins.

The BIAS supply can be between 4.0V to 5.5V, while the OVP_TRIP point depends on the BIAS supply voltage accuracy. Otherwise an accurate reference can be derived from the BIAS supply.

RUNP and RUNC Enable

The RUNP pin is used to enable the 5V PV_{CC} supply that powers the power driver stage and enables the power stage ~1ms later. The RUNC pin is used to enable the control section that drives the power stage. The RUNP needs to be enabled first, and then RUNC. RUNP has a 0.85V threshold and can be connected to the input voltage and RUNC has a 1.35V threshold and a 10k resistor to ground. See the Block Diagram for details. A 0.1 μ F capacitor from the RUNC pin to ground is used to set the delay for RUNC enable.

INTV_{CC} and PV_{CC} Regulators

The LTM4636-1 has an internal low dropout regulator from V_{IN} called INTV_{CC}. This regulator output has a 4.7 μ F ceramic capacitor internal. This regulator powers the control section. The PV_{CC} 5V regulator supplies power to the power MOSFET driver stage. An additional 50mA can be used from this 5V PV_{CC} supply for other needs. The input supply source resistance needs to be very low in order to minimize IR drops when operating from a 5V input source. Depending on the output voltage and current, the input supply can source large current, and PV_{CC} 5V regulator needs a minimum 4.7V supply. Additional input capacitance maybe needed for 5V inputs to limit the input droop.

Stability Compensation

The LTM4636-1 has already been internally compensated when COMPB is tied to COMPA for all output voltages. Table 5 is provided for most application requirements. For specific optimized requirements, disconnect COMPB from COMPA, and use LTpowerCAD to perform specific control loop optimization. Then select the desired external compensation and output capacitance for the desired optimized response.

SW Pins

The SW pins are generally for testing purposes by monitoring these pins. These pins can also be used to dampen out switch node ringing caused by LC parasitic in the switched current paths. Usually a series R-C combination is used called a snubber circuit. The resistor will dampen the resonance and the capacitor is chosen to only affect the high frequency ringing across the resistor. If the stray inductance or capacitance can be measured or approximated then a somewhat analytical technique can be used to select the snubber values. The inductance is usually easier to predict. It combines the power path board inductance in combination with the MOSFET interconnect bond wire inductance.

First the SW pin can be monitored with a wide bandwidth scope with a high frequency scope probe. The ring frequency can be measured for its value. The impedance Z can be calculated:

 $Z(L) = 2\pi f L,$

where f is the resonant frequency of the ring, and L is the total parasitic inductance in the switch path. If a resistor is selected that is equal to Z, then the ringing should be dampened. The snubber capacitor value is chosen so that its impedance is equal to the resistor at the ring frequency. Calculated by: $Z(C) = 1/(2\pi fC)$. These values are a good place to start with. Modification to these components should be made to attenuate the ringing with the least amount of power loss. A recommended value of 2.2Ω in series with 2200pF to ground should work for most applications. See Figure 19 for layout guidelines. The 2.2Ω resistor should be an 0805 size.

Thermal Considerations and Output Current Derating

The thermal resistances reported in the Pin Configuration section of the data sheet are consistent with those parameters defined by JESD51-12 and are intended for use with finite element analysis (FEA) software modeling tools that leverage the outcome of thermal modeling, simulation, and correlation to hardware evaluation performed on a μ Module package mounted to a hardware test board. The motivation for providing these thermal coefficients in found in JESD51-12 ("Guidelines for Reporting and Using Electronic Package Thermal Information").

Many designers may opt to use laboratory equipment and a test vehicle such as the demo board to predict the μ Module regulator's thermal performance in their application at various electrical and environmental operating conditions to compliment any FEA activities. Without FEA software, the thermal resistances reported in the Pin Configuration section are, in and of themselves, not relevant to providing guidance of thermal performance; instead, the derating

curves provided in this data sheet can be used in a manner that yields insight and guidance pertaining to one's application usage, and can be adapted to correlate thermal performance to one's own application.

The Pin Configuration section gives four thermal coefficients explicitly defined in JESD51-12; these coefficients are quoted or paraphrased below:

- 1. θ_{JA} , the thermal resistance from junction to ambient, is the natural convection junction-to-ambient air thermal resistance measured in a one cubic foot sealed enclosure. This environment is sometimes referred to as "still air" although natural convection causes the air to move. This value is determined with the part mounted to a 95mm × 76mm PCB with four layers.
- 2. $\theta_{JCbottom}$, the thermal resistance from junction to the bottom of the product case, is determined with all of the component power dissipation flowing through the bottom of the package. In the typical µModule regulator, the bulk of the heat flows out the bottom of the package, but there is always heat flow out into the ambient environment. As a result, this thermal resistance value may be useful for comparing packages but the test conditions don't generally match the user's application.
- 3 θ_{JCtop} , the thermal resistance from junction to top of the product case, is determined with nearly all of the component power dissipation flowing through the top of the package. As the electrical connections of the typical µModule regulator are on the bottom of the

package, it is rare for an application to operate such that most of the heat flows from the junction to the top of the part. As in the case of $\theta_{JCbottom}$, this value may be useful for comparing packages but the test conditions don't generally match the user's application.

4 θ_{JB} , the thermal resistance from junction to the printed circuit board, is the junction-to-board thermal resistance where almost all of the heat flows through the bottom of the μ Module package and into the board, and is really the sum of the $\theta_{JCbottom}$ and the thermal resistance of the bottom of the part through the solder joints and a portion of the board. The board temperature is measured a specified distance from the package.

A graphical representation of the aforementioned thermal resistances is given in Figure 9; blue resistances are contained within the μ Module regulator, whereas green resistances are external to the μ Module package.

As a practical matter, it should be clear to the reader that no individual or sub-group of the four thermal resistance parameters defined by JESD51-12 or provided in the Pin Configuration section replicates or conveys normal operating conditions of a µModule regulator. For example, in normal board-mounted applications, never does 100% of the device's total power loss (heat) thermally conduct exclusively through the top or exclusively through the bottom of the µModule package—as the standard defines for θ_{JCtop} and $\theta_{JCbottom}$, respectively. In practice, power loss is thermally dissipated in both directions away from the package—granted, in the absence of a heat sink and airflow, a majority of the heat flow is into the board.

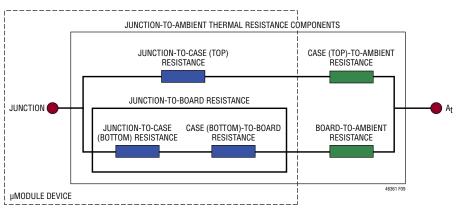


Figure 9. Graphical Representation of JESD51-12 Thermal Coefficients

Within the LTM4636-1, be aware there are multiple power devices and components dissipating power, with a consequence that the thermal resistances relative to different junctions of components or die are not exactly linear with respect to total package power loss. To reconcile this complication without sacrificing modeling simplicity-but also not ignoring practical realities—an approach has been taken using FEA software modeling along with laboratory testing in a controlled-environment chamber to reasonably define and correlate the thermal resistance values supplied in this data sheet: (1) Initially, FEA software is used to accurately build the mechanical geometry of the LTM4636-1 and the specified PCB with all of the correct material coefficients along with accurate power loss source definitions: (2) this model simulates a softwaredefined JEDEC environment consistent with JESD51-12 to predict power loss heat flow and temperature readings at different interfaces that enable the calculation of the JEDEC-defined thermal resistance values; (3) the model and FEA software is used to evaluate the LTM4636-1 with heat sink and airflow; (4) having solved for and analyzed these thermal resistance values and simulated various operating conditions in the software model, a thorough laboratory evaluation replicates the simulated conditions with thermocouples within a controlled-environment chamber while operating the device at the same power loss as that which was simulated. The outcome of this process and due diligence yields the set of derating curves shown in this data sheet.

The power loss curves in Figure 10 to Figure 12 can be used in coordination with the load current derating curves in Figure 13 to Figure 18 for calculating an approximate θ_{JA} thermal resistance for the LTM4636-1 with various airflow conditions. The power loss curves are taken at room temperature and can be increased with a multiplicative factor according to the junction temperature, which is ~1.4 for 120°C. The derating curves are plotted with the output current starting at 40A and the ambient temperature increased. The output voltages are 1V, 2.5V and 3.3V. These are chosen to include the lower, middle and higher output voltage ranges for correlating the thermal resistance. Thermal models are derived from several temperature measurements in a controlled temperature chamber along with thermal modeling analysis. The junction temperatures are monitored while

ambient temperature is increased with and without airflow. The power loss increase with ambient temperature change is factored into the derating curves. The junctions are maintained at ~125°C maximum while lowering output current or power with increasing ambient temperature. The decreased output current will decrease the internal module loss as ambient temperature is increased. The monitored junction temperature of 125°C minus the ambient operating temperature specifies how much module temperature rise can be allowed. As an example, in Figure 14 the load current is derated to ~30A at ~94°C with no air flow and the power loss for the 12V to 1.0V at 30A output is about 4.2W. The 4.2W loss is calculated with the ~3W room temperature loss from the 12V to 1.0V power loss curve at 30A, and the 1.4 multiplying factor at 125°C junction. If the 94°C ambient temperature is subtracted from the 125°C junction temperature, then the difference of 31°C divided by 4.2W equals a 7.4°C/W θ_{IA} thermal resistance. Table 2 specifies a 7.2°C/W value which is very close. Tables 2, 3, and 4 provide equivalent thermal resistances for 1V, 1.5V and 3.3V outputs with and without airflow and heat sinking. The derived thermal resistances in Tables 2 thru 4 for the various conditions can be multiplied by the calculated power loss as a function of ambient temperature to derive temperature rise above ambient, thus maximum junction temperature. Room temperature power loss curves are provided in Figure 10 through Figure 12. The printed circuit board is a 1.6mm thick six layer board with two ounce copper for all layers and one ounce copper for the two inner layers. The PCB dimensions are 95mm × 76mm.

Safety Considerations

The LTM4636-1 does not provide galvanic isolation from V_{IN} to V_{OUT} . There is no internal fuse. If required, a slow blow fuse with a rating twice the maximum input current needs to be provided to protect each unit from catastrophic failure.

The fuse or circuit breaker should be selected to limit the current to the regulator during overvoltage in case of an internal top MOSFET fault. If the internal top MOSFET fails, then turning it off will not resolve the overvoltage, thus the internal bottom MOSFET will turn on indefinitely trying to protect the load. Under this fault condition, the

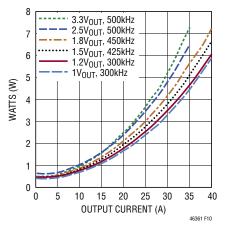


Figure 10. 5V Input Power Loss Curves

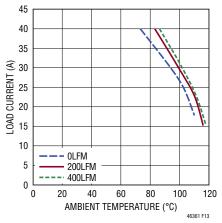


Figure 13. 5V_{IN}, 1V_{OUT} Derate Curve

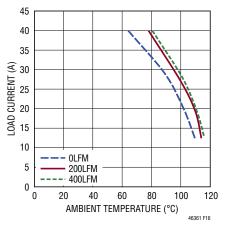


Figure 16. $12V_{IN}$, $1.5V_{OUT}$ Derate Curve

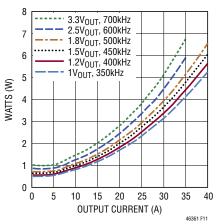
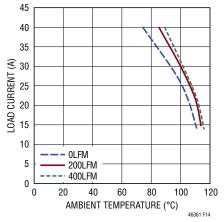
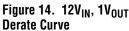


Figure 11. 8V Input Power Loss Curves





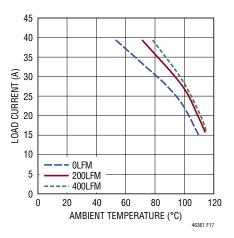


Figure 17. 5V_{IN}, 3.3V_{OUT} Derate Curve

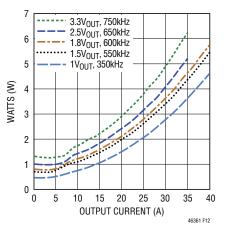


Figure 12. 12V Input Power Loss Curves

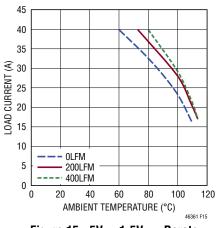


Figure 15. $5V_{IN}$, 1. $5V_{OUT}$ Derate Curve

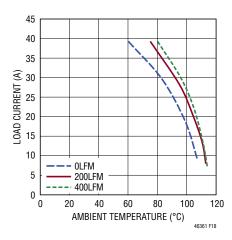


Figure 18. $12V_{IN}$, $3.3V_{OUT}$ Derate Curve

Table 2. 1V Output

| DERATING CURVE | V _{IN} | POWER LOSS CURVE | AIRFLOW (LFM) | θ _{JA} (°C/W) |
|-------------------|-----------------|---------------------|------------------|------------------------|
| Figures 13, 14 | 5V, 12V | Figure 10, 12 | 0 | 7.2 |
| Figures 13, 14 | 5V, 12V | Figure 10, 12 | 200 | 5.4 |
| Figures 13, 14 | 5V, 12V | Figure 10, 12 | 400 | 4.8 |

Table 3. 1.5V Output

| DERATING CURVE | V _{IN} | POWER LOSS CURVE | AIRFLOW (LFM) | θ _{JA} (°C/W) |
|-------------------|-----------------|---------------------|------------------|------------------------|
| Figures 15, 16 | 5V, 12V | Figure 10, 12 | 0 | 7.4 |
| Figures 15, 16 | 5V, 12V | Figure 10, 12 | 200 | 5.0 |
| Figures 15, 16 | 5V, 12V | Figure 10, 12 | 400 | 4.5 |

Table 4. 3.3V

| DERATING CURVE | V _{IN} | POWER LOSS CURVE | AIRFLOW (LFM) | θ _{JA} (°C/W) |
|-------------------|-----------------|---------------------|------------------|------------------------|
| Figures 17, 18 | 12V | Figure 10, 12 | 0 | 7.4 |
| Figures 17, 18 | 12V | Figure 10, 12 | 200 | 5.0 |
| Figures 17, 18 | 12V | Figure 10, 12 | 400 | 4.4 |

Table 5. LTM4636-1 Capacitor Matrix, All Below Parameters are Typical and are Dependent on Board Layout

| Taiyo Yuden | 22µF, 25V | C3216X7S0J226M | Panasonic SP | 470µF 2.5V | EEFGX0E471R | Sanyo | 20SEP100M | 100µF 20V |
|-------------|-------------|--------------------|------------------|------------|-------------|-------|-----------|-----------|
| Murata | 22µF, 25V | GRM31CR61C226KE15L | Panasonic POSCAP | 470µF 2R5 | 2R5TPD470M5 | | | |
| Murata | 100µF, 6.3V | GRM32ER60J107M | Panasonic POSCAP | 470µF 6.3V | 6TPD470M5 | | | |
| AVX | 100µF, 6.3V | 18126D107MAT | | | | | | |
| Taiyo Yuden | 220µF, 4V | | | | | | | |
| Murata | 220µF, 4V | | | | | | | |

| V _{OUT} (V) | C _{in} (Ceramic) | C _{IN} (BULK) | C _{out1} (ceramic) and C _{out2} (ceramic and bulk) | C _{FF} * (pf) | C _{COMP} (pf) | V _{IN} (V) | DROOP (mV) | PEAK-TO-PEAK DEVIATION (mV) | RECOVERY TIME (µs) | LOAD Step (A/µs) | R _{FB} (kΩ) | FREQ (kHz) |
|-------------------------|------------------------------|---------------------------|---|---------------------------|---------------------------|------------------------|---------------|-----------------------------------|-----------------------|------------------------|-------------------------|-----------------------|
| 0.9 | 22µF × 5 | 100µF | 100µF × 8, 470µF × 3 | 22 | 100 | 5,12 | 38 | 76 | 40 | 15 | 10 | 350 |
| 0.9 | 22µF × 5 | 100µF | 220µF × 6, 470µF × 2 | 68 | 100 | 5,12 | 40 | 80 | 30 | 15 | 10 | 350 |
| 0.9 | 22µF × 5 | 100µF | 220µF × 10, 470µF | None | 220 | 5,12 | 40 | 80 | 30 | 15 | 10 | 350 |
| 1 | 22µF × 5 | 100µF | 100μF × 4, 470μF × 3 | None | 100 | 5,12 | 40 | 80 | 30 | 15 | 7.5 | 350 |
| 1 | 22µF × 5 | 100µF | 100μF × 6, 470μF × 2 | None | 100 | 5,12 | 50 | 100 | 30 | 15 | 7.5 | 350 |
| 1 | 22µF × 5 | 100µF | 100μF × 8, 470μF × 2 | None | 150 | 5,12 | 55 | 105 | 30 | 15 | 7.5 | 350 |
| 1.2 | 22µF × 5 | 100µF | 100µF × 4, 470µF × 3 | None | 100 | 5,12 | 45 | 90 | 35 | 15 | 4.99 | 350 |
| 1.2 | 22µF × 5 | 100µF | 100μF × 6, 470μF × 2 | None | 100 | 5,12 | 45 | 90 | 35 | 15 | 4.99 | 400 |
| 1.2 | 22µF × 5 | 100µF | 220μF × 4, 470μF | None | 100 | 5,12 | 50 | 104 | 30 | 15 | 4.99 | 400 |
| 1.5 | 22µF × 5 | 100µF | 100μF × 4, 470μF × 3 | None | 100 | 5,12 | 60 | 120 | 35 | 15 | 3.24 | 425 |
| 1.5 | 22µF × 5 | 100µF | 100μF × 4, 470μF × 2 | None | 100 | 5,12 | 56 | 110 | 35 | 15 | 3.24 | 425 |
| 1.5 | 22µF × 5 | 100µF | 100μF × 3, 470μF | None | 100 | 5,12 | 75 | 150 | 25 | 15 | 3.24 | 425 |
| 1.8 | 22µF × 5 | 100µF | 100μF × 3, 470μF | None | 220 | 5,12 | 90 | 180 | 25 | 15 | 2.49 | 500 |
| 1.8 | 22µF × 5 | 100µF | 100µF, 470µF | None | 220 | 5,12 | 95 | 197 | 24 | 15 | 2.49 | 500 |
| 1.8 | 22µF × 5 | 100µF | 220μF × 2, 470μF | None | 220 | 5,12 | 90 | 180 | 20 | 15 | 2.49 | 500 |
| 2.5 | 22µF × 5 | 100µF | 100μF × 2, 470μF | None | 220 | 5,12 | 120 | 220 | 30 | 15 | 1.58 | 650 (12V) 500 (5V) |
| 2.5 | 22µF × 5 | 100µF | 100μF × 6, 470μF | 22 | 220 | 5,12 | 87 | 174 | 40 | 15 | 1.58 | 650 (12V) 500 (5V) |
| 3.3 | 22µF × 5 | 100µF | 100µF × 4 | 220 | 220 | 5,12 | 130 | 260 | 25 | 15 | 1.1 | 750 (12V) 500 (5V) |
| 3.3 | 22µF × 5 | 100µF | 100µF, 470µF | None | 220 | 5,12 | 140 | 280 | 30 | 15 | 1.1 | 750 (12V) 500 (5V) |

 * C_{FF} is a capacitor from V_{OUT} to V_{FB}.

Table 6. Enhanced External Compensation, Lower Voltage Transition During Transient. Careful Power Integrity Layout Required

| V _{OUT} (V) | C _{in} (Ceramic) | C _{IN} (BULK) [†] | C _{out1} (Ceramic) and C _{out2} (Ceramic and Bulk) | C _{FF} (pf) | C _{COMP} (pf) | V _{IN} (V) | DROOP (mV) | PEAK-TO-PEAK Deviation (mV) | | - | | FREQ (kHz) | R _{COMP} (k) | C _{COMP} (pF) |
|-------------------------|------------------------------|--|---|-------------------------|---------------------------|------------------------|---------------|--------------------------------|----|----|------|---------------|--------------------------|---------------------------|
| 0.9 | 22µF × 5 | 100µF | 220µF × 10, 470µF | 47 | 100 | 5, 12 | 25 | 50 | 26 | 15 | 10 | 350 | 15 | 1000 |
| 1 | 22µF × 5 | 100µF | 220µF × 10, 470µF | 47 | 100 | 5, 12 | 28 | 55 | 25 | 15 | 7.5 | 350 | 15 | 1000 |
| 1.2 | 22µF × 5 | 100µF | 220µF × 10, 470µF | 47 | 100 | 5, 12 | 33 | 66 | 30 | 15 | 4.99 | 350 | 15 | 1000 |

 $^{\rm +}$ Bulk capacitance is optional if $V_{\rm IN}$ has very low input impedance

input voltage will source very large currents to ground through the failed internal top MOSFET and enabled internal bottom MOSFET. This can cause excessive heat and board damage depending on how much power the input voltage can deliver to this system. A fuse or circuit breaker can be used as a secondary fault protector in this situation. The LTM4636-1 has the enhanced over temperature protection discussed earlier and schematic applications will be shown at the end of the data sheet.

Layout Checklist/Example

The high integration of the LTM4636-1 makes the PCB board layout very simple and easy. However, to optimize its electrical and thermal performance, some layout considerations are still necessary.

- Use large PCB copper areas for high current paths, including $V_{\text{IN}},$ GND and $V_{\text{OUT}}.$ It helps to minimize the PCB conduction loss and thermal stress.
- Place high frequency ceramic input and output capacitors next to the V_{IN}, GND and V_{OUT} pins to minimize high frequency noise.

- Place a dedicated power ground layer underneath the unit.
- To minimize the via conduction loss and reduce module thermal stress, use multiple vias for interconnection between top layer and other power layers.
- Do not put vias directly on the pad, unless they are capped or plated over.
- Place test points on signal pins for testing.
- Use a separated SGND ground copper area for components connected to signal pins. Connect the SGND to GND underneath the unit.
- For parallel modules, tie the COMP and V_{FB} pins together. Use an internal layer to closely connect these pins together.
- Add R_{SNUB} (2.2 Ω) and C_{SNUB} (2200 pF) to dampen switch ringing.

Figure 19 gives a good example of the recommended layout.

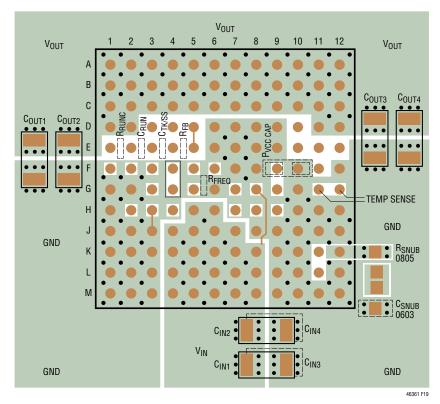


Figure 19. Recommended PCB Layout

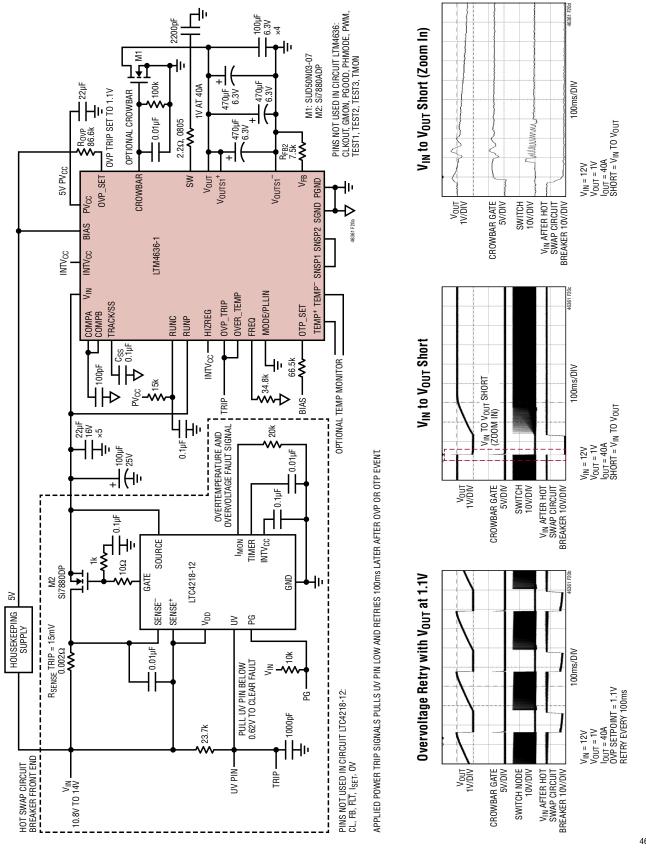
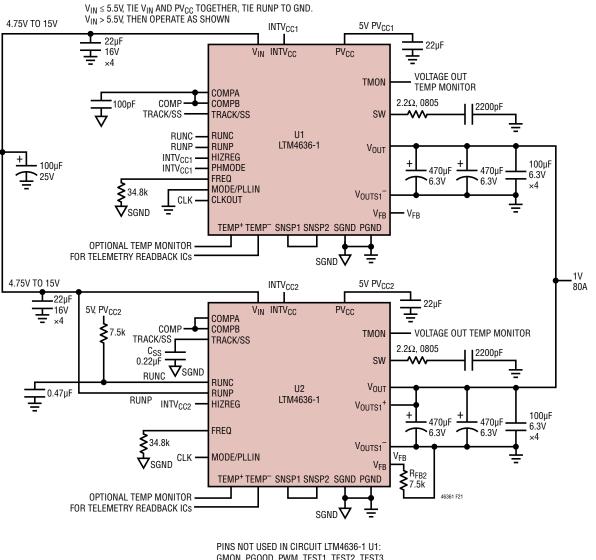


Figure 20. 10.8V to 14V, 1V at 40A Design with Protection

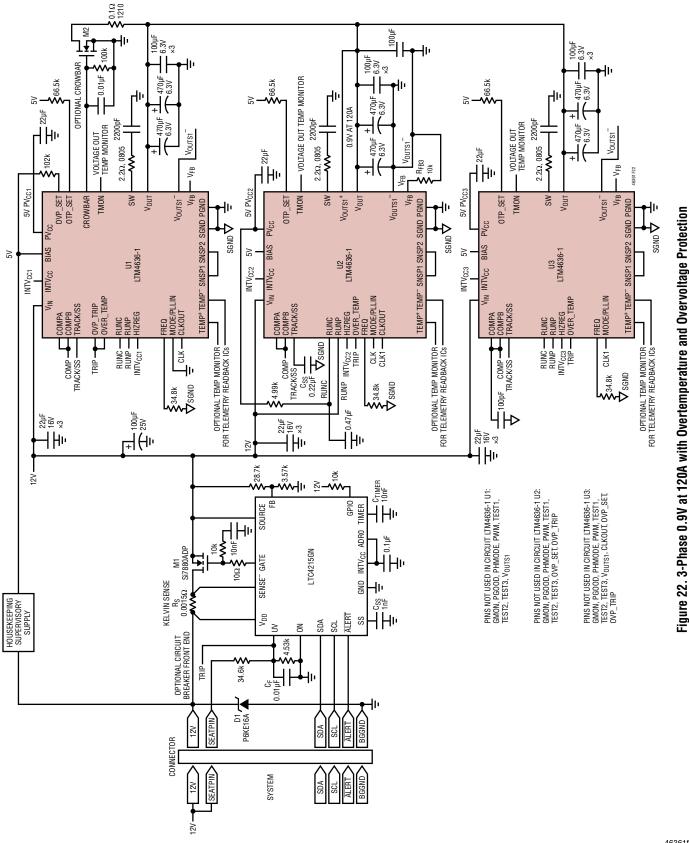


MON. PGOOD, PWM, TEST1, TEST2, TEST3, V_{OSNS1}⁺, CROWBAR, OTP_SET, OVP_SET, BIAS, OVP_TRIP, OVER_TEMP

PINS NOT USED IN CIRCUIT LTM4636-1 U2: GMON, PGOOD, PHMODE, PWM, TEST1, TEST2, TEST3, CROWBAR, OTP_SET, OVP_SET, BIAS, OVP_TRIP, OVER_TEMP

Figure 21. 2-Phase 1V, 80A Regulator Design





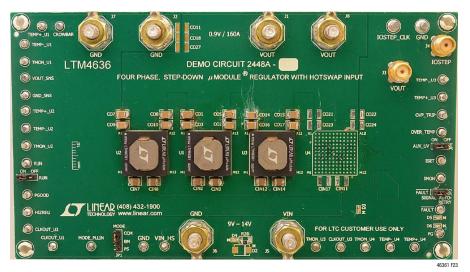


Figure 23. DC2448A Demo Board

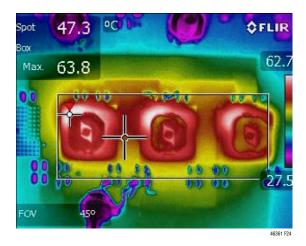


Figure 24. Thermal Plot, 12V to 0.9V at 120A, 400LFM Air Flow

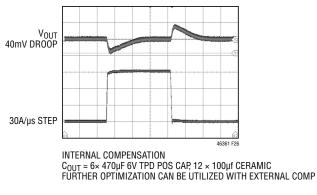


Figure 26. 12V to 0.9V 30A/µs Load Step

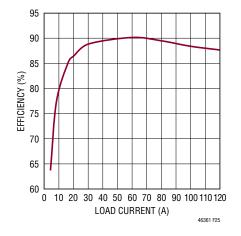
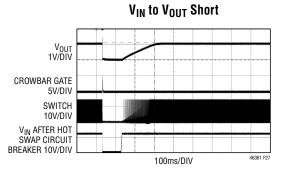


Figure 25. Efficiency, 12V to 0.9V at 120A





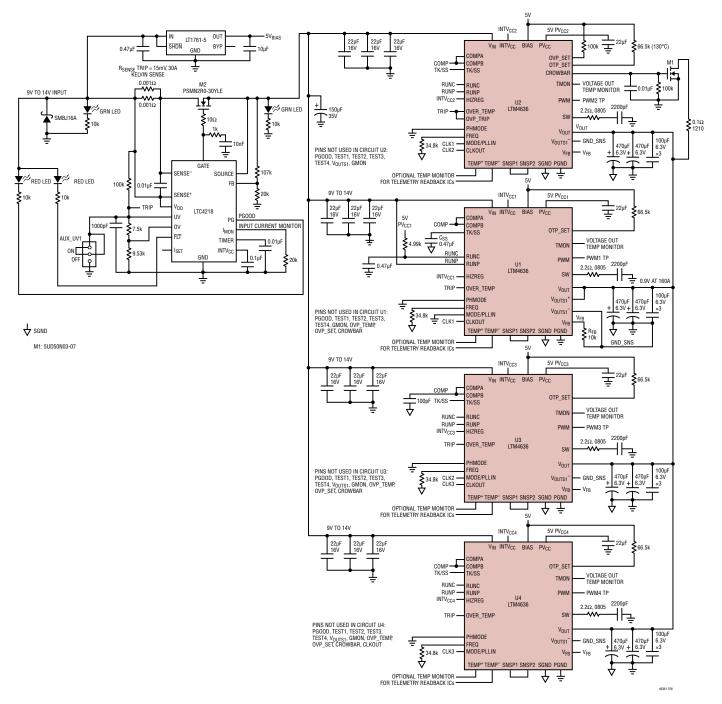


Figure 28. 12V to 0.9V, A1/60A with Circuit Breaker Front End and Overtemperature and Overvoltage Protection

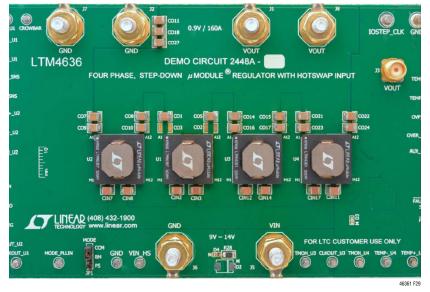
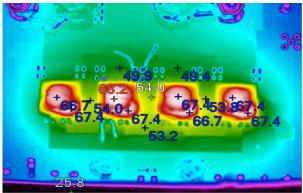
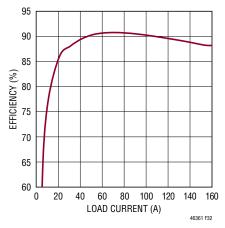


Figure 29. DC2448A Demo Board

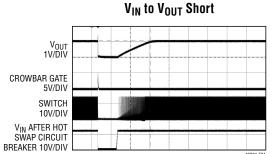


46361 F30

Figure 30. Thermal Plot, 12V to 0.9V at 160A, 400LFM Air Flow







100ms/DIV Figure 31. 12V to 0.9V Overvoltage Trip

46361 F31

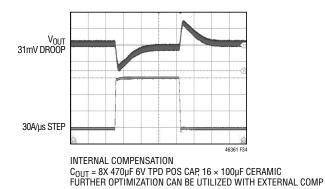


Figure 33. 12V to 0.9V 30A/µs Load Step

PACKAGE DESCRIPTION



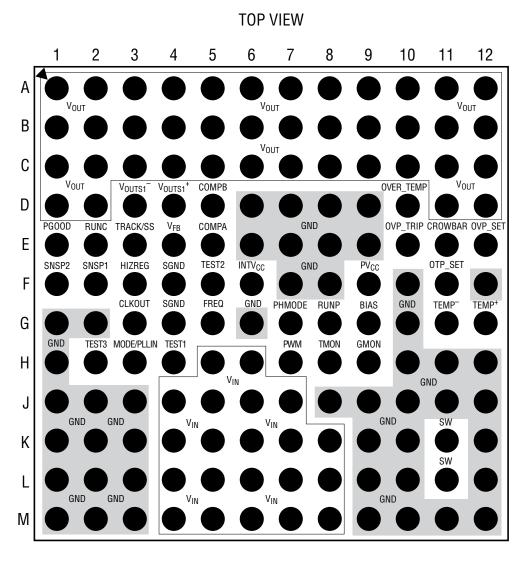
PACKAGE ROW AND COLUMN LABELING MAY VARY AMONG µModule PRODUCTS. REVIEW EACH PACKAGE LAYOUT CAREFULLY.

Pin Assignment Table (Arranged by Pin Number)

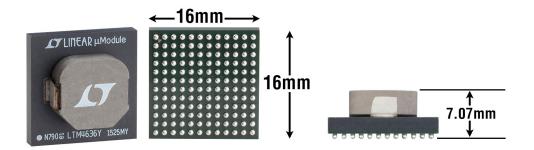
| PIN ID | FUNCTION | PIN ID | FUNCTION | PIN ID | FUNCTION |
|--------|------------------|--------|------------------|--------|------------------|--------|---------------------------------|--------|-----------------|--------|--------------------|
| A1 | V _{OUT} | B1 | V _{OUT} | C1 | V _{OUT} | D1 | V _{OUT} | E1 | PGOOD | F1 | SNSP2 |
| A2 | V _{OUT} | B2 | V _{OUT} | C2 | V _{OUT} | D2 | V _{OUT} | E2 | RUNC | F2 | SNSP1 |
| A3 | V _{OUT} | B3 | V _{OUT} | C3 | V _{OUT} | D3 | V _{OUTS1} ⁻ | E3 | TRACK/SS | F3 | HIZREG |
| A4 | V _{OUT} | B4 | V _{OUT} | C4 | V _{OUT} | D4 | V _{OUTS1} + | E4 | V _{FB} | F4 | SGND |
| A5 | V _{OUT} | B5 | V _{OUT} | C5 | V _{OUT} | D5 | COMPB | E5 | COMPA | F5 | TEST2 |
| A6 | V _{OUT} | B6 | V _{OUT} | C6 | V _{OUT} | D6 | GND | E6 | GND | F6 | INTV _{CC} |
| A7 | V _{OUT} | B7 | V _{OUT} | C7 | V _{OUT} | D7 | GND | E7 | GND | F7 | GND |
| A8 | V _{OUT} | B8 | V _{OUT} | C8 | V _{OUT} | D8 | GND | E8 | GND | F8 | GND |
| A9 | V _{OUT} | B9 | V _{OUT} | C9 | V _{OUT} | D9 | GND | E9 | GND | F9 | PV _{CC} |
| A10 | V _{OUT} | B10 | V _{OUT} | C10 | V _{OUT} | D10 | OVER_TEMP | E10 | OVP_TRIP | F10 | GND |
| A11 | V _{OUT} | B11 | V _{OUT} | C11 | V _{OUT} | D11 | V _{OUT} | E11 | CROWBAR | F11 | OTP_SET |
| A12 | V _{OUT} | B12 | V _{OUT} | C12 | V _{OUT} | D12 | V _{OUT} | E12 | OVP_SET | F12 | GND |

| PIN ID | FUNCTION | PIN ID | FUNCTION | PIN ID | FUNCTION | PIN ID | FUNCTION | PIN ID | FUNCTION | PIN ID | FUNCTION |
|--------|-------------------|--------|-----------------|--------|-----------------|--------|-----------------|--------|-----------------|--------|-----------------|
| G1 | GND | H1 | GND | J1 | GND | K1 | GND | L1 | GND | M1 | GND |
| G2 | GND | H2 | TEST3 | J2 | GND | K2 | GND | L2 | GND | M2 | GND |
| G3 | CLKOUT | H3 | MODE/PLLIN | J3 | GND | K3 | GND | L3 | GND | M3 | GND |
| G4 | SGND | H4 | TEST1 | J4 | V _{IN} | K4 | V _{IN} | L4 | V _{IN} | M4 | V _{IN} |
| G5 | FREQ | H5 | V _{IN} | J5 | V _{IN} | K5 | V _{IN} | L5 | V _{IN} | M5 | V _{IN} |
| G6 | GND | H6 | V _{IN} | J6 | V _{IN} | K6 | V _{IN} | L6 | V _{IN} | M6 | V _{IN} |
| G7 | PHMODE | H7 | PWM | J7 | V _{IN} | K7 | V _{IN} | L7 | V _{IN} | M7 | V _{IN} |
| G8 | RUNP | H8 | TMON | J8 | GND | K8 | V _{IN} | L8 | V _{IN} | M8 | V _{IN} |
| G9 | BIAS | H9 | GMON | J9 | GND | K9 | GND | L9 | GND | M9 | GND |
| G10 | GND | H10 | GND | J10 | GND | K10 | GND | L10 | GND | M10 | GND |
| G11 | TEMP ⁻ | H11 | GND | J11 | GND | K11 | SW | L11 | SW | M11 | GND |
| G12 | TEMP ⁺ | H12 | GND | J12 | GND | K12 | GND | L12 | GND | M12 | GND |

PACKAGE DESCRIPTION

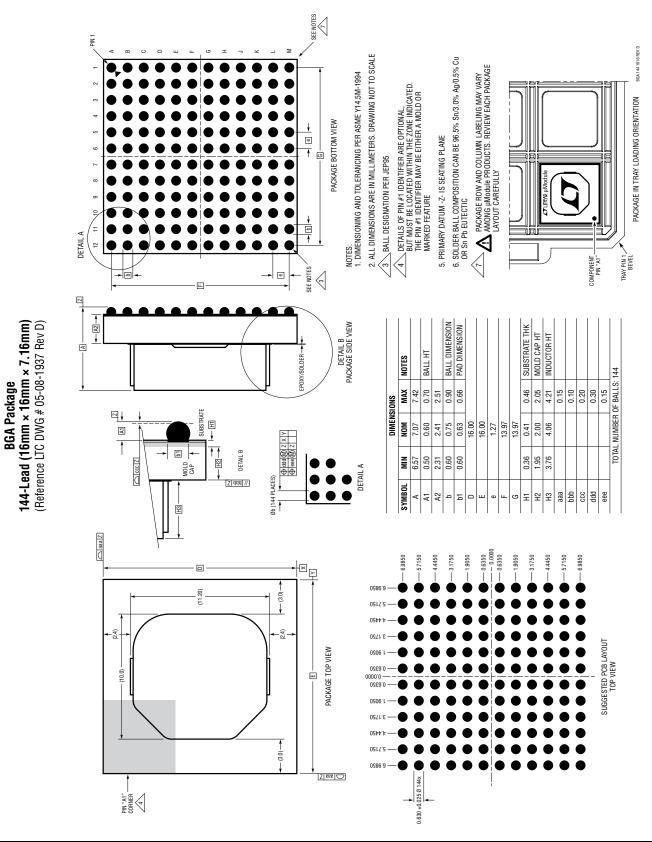


PACKAGE PHOTO



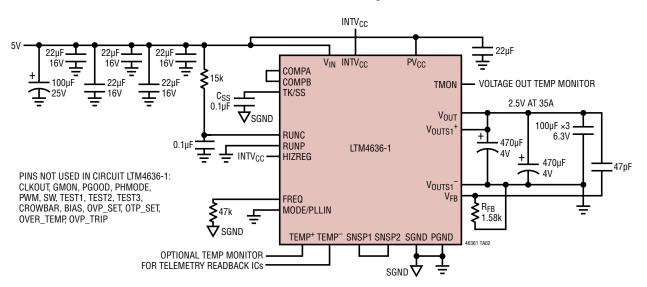
PACKAGE DESCRIPTION

Please refer to http://www.linear.com/product/LTM4636-1#packaging for the most recent package drawings.



REVISION HISTORY

| REV | DATE | DESCRIPTION | PAGE NUMBER |
|-----|-------|---|-------------|
| Α | 12/17 | Changed Turn-On-Time TYP from 50ms to 750µs | 3 |



5V to 2.5V at 30A Design

DESIGN RESOURCES

| SUBJECT | DESCRIPTION | | | | | | |
|--|--|--|--|--|--|--|--|
| µModule Design and Manufacturing Resources | Design: • Selector Guides • Demo Boards and Gerber Files • Free Simulation Tools Manufacturing: • Quick Start Guide • PCB Design, Assembly and Manufacturing Guidelines • Package and Board Level Reliability | | | | | | |
| µModule Regulator Products Search | Sort table of products by parameters and download the result as a spread sheet. Search using the Quick Power Search parametric table. Quick Power Search Input V_{in} (Min) V V_{in} (Max) V Output V_{out} V | | | | | | |
| TechClip Videos | Quick videos detailing how to bench test electrical and thermal performance of µModule products. | | | | | | |
| Digital Power System Management | Linear Technology's family of digital power supply management ICs are highly integrated solutions that offer essential functions, including power supply monitoring, supervision, margining and sequencing, and feature EEPROM for storing user configurations and fault logging. | | | | | | |

RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|-------------|--|---|
| LTM4609 | Buck-Boost DC/DC µModule Family | All Pin Compatible; Up to 5A; Up to $36V_{IN}$, $34V_{OUT}$ 15mm × 15mm × 2.82mm |
| LTM4612 | Ultralow Noise High V _{OUT} DC/DC µModule Regulator | 5A, 5V \leq V _{IN} \leq 36V, 3.3V \leq V _{OUT} \leq 15V, 15mm \times 15mm \times 2.82mm Package |
| LTM4627 | 15A DC/DC μModule Regulator | $4.5V \leq V_{IN} \leq 20V, 0.6V \leq V_{OUT} \leq 5V, LGA and BGA Packages$ |
| LTM4620 | Dual 13A, Single 26A DC/DC µModule Regulator | Up to 100A with Four in Parallel, $4.5V \le V_{IN} \le 16V, 0.6V \le V_{OUT} \le 2.5V$ |
| LTM4636 | LTM4636-1 without Overvoltage/Overtemperature Protection | $4.75V \le V_{IN} \le 15V$, $0.6V \le V_{OUT} \le 3.3V$, $16mm \times 16mm \times 7.12mm$ BGA |

